

# **μPD44325092B**

# **μPD44325182B**

# **μPD44325362B**

**36M-BIT QDR™ II SRAM**  
**2-WORD BURST OPERATION**

R10DS0038EJ0200  
 Rev.2.00  
 August 11, 2011

## **Description**

The μPD44325092B is a 4,194,304-word by 9-bit, the μPD44325182B is a 2,097,152-word by 18-bit and the μPD44325362B is a 1,048,576-word by 36-bit synchronous quad data rate static RAM fabricated with advanced CMOS technology using full CMOS six-transistor memory cell.

The μPD44325092B, μPD44325182B and μPD44325362B integrate unique synchronous peripheral circuitry and a burst counter. All input registers controlled by an input clock pair (K and K#) are latched on the positive edge of K and K#. These products are suitable for application which require synchronous operation, high speed, low voltage, high density and wide bit configuration. These products are packaged in 165-pin PLASTIC BGA.

## **Features**

- 1.8 ± 0.1 V power supply
- 165-pin PLASTIC BGA (15 x 17)
- HSTL interface
- PLL circuitry for wide output data valid window and future frequency scaling
- Separate independent read and write data ports with concurrent transactions
- 100% bus utilization DDR READ and WRITE operation
- Two-tick burst for low DDR transaction size
- Two input clocks (K and K#) for precise DDR timing at clock rising edges only
- Two output clocks (C and C#) for precise flight time and clock skew matching-clock and data delivered together to receiving device
- Internally self-timed write control
- Clock-stop capability. Normal operation is restored in 20 μs after clock is resumed.
- User programmable impedance output (35 to 70 Ω)
- Fast clock cycle time : 3.3 ns (300 MHz), 3.5 ns (287 MHz), 4.0 ns (250 MHz), 5.0 ns (200 MHz)
- Simple control logic for easy depth expansion
- JTAG 1149.1 compatible test access port

## Ordering Information (1/2)

| Part No.                 | Organization<br>(word x bit) | Cycle<br>time | Clock<br>frequency | Operating Ambient<br>Temperature | Package                                          |
|--------------------------|------------------------------|---------------|--------------------|----------------------------------|--------------------------------------------------|
| μPD44325092BF5-E33-FQ1-A | 4M x 9                       | 3.3ns         | 300MHz             | Ta = 0 to 70°C                   | 165-pin<br>PLASTIC BGA<br>(15 x 17)<br>Lead-free |
| μPD44325092BF5-E35-FQ1-A |                              | 3.5ns         | 287MHz             |                                  |                                                  |
| μPD44325092BF5-E40-FQ1-A |                              | 4.0ns         | 250MHz             |                                  |                                                  |
| μPD44325092BF5-E50-FQ1-A |                              | 5.0ns         | 200MHz             |                                  |                                                  |
| μPD44325182BF5-E33-FQ1-A | 2M x 18                      | 3.3ns         | 300MHz             |                                  |                                                  |
| μPD44325182BF5-E35-FQ1-A |                              | 3.5ns         | 287MHz             |                                  |                                                  |
| μPD44325182BF5-E40-FQ1-A |                              | 4.0ns         | 250MHz             |                                  |                                                  |
| μPD44325182BF5-E50-FQ1-A |                              | 5.0ns         | 200MHz             |                                  |                                                  |
| μPD44325362BF5-E33-FQ1-A | 1M x 36                      | 3.3ns         | 300MHz             |                                  |                                                  |
| μPD44325362BF5-E35-FQ1-A |                              | 3.5ns         | 287MHz             |                                  |                                                  |
| μPD44325362BF5-E40-FQ1-A |                              | 4.0ns         | 250MHz             |                                  |                                                  |
| μPD44325362BF5-E50-FQ1-A |                              | 5.0ns         | 200MHz             |                                  |                                                  |
| μPD44325092BF5-E33-FQ1   | 4M x 9                       | 3.3ns         | 300MHz             | Ta = 0 to 70°C                   | 165-pin<br>PLASTIC BGA<br>(15 x 17)<br>Lead      |
| μPD44325092BF5-E35-FQ1   |                              | 3.5ns         | 287MHz             |                                  |                                                  |
| μPD44325092BF5-E40-FQ1   |                              | 4.0ns         | 250MHz             |                                  |                                                  |
| μPD44325092BF5-E50-FQ1   |                              | 5.0ns         | 200MHz             |                                  |                                                  |
| μPD44325182BF5-E33-FQ1   | 2M x 18                      | 3.3ns         | 300MHz             |                                  |                                                  |
| μPD44325182BF5-E35-FQ1   |                              | 3.5ns         | 287MHz             |                                  |                                                  |
| μPD44325182BF5-E40-FQ1   |                              | 4.0ns         | 250MHz             |                                  |                                                  |
| μPD44325182BF5-E50-FQ1   |                              | 5.0ns         | 200MHz             |                                  |                                                  |
| μPD44325362BF5-E33-FQ1   | 1M x 36                      | 3.3ns         | 300MHz             |                                  |                                                  |
| μPD44325362BF5-E35-FQ1   |                              | 3.5ns         | 287MHz             |                                  |                                                  |
| μPD44325362BF5-E40-FQ1   |                              | 4.0ns         | 250MHz             |                                  |                                                  |
| μPD44325362BF5-E50-FQ1   |                              | 5.0ns         | 200MHz             |                                  |                                                  |

## Ordering Information (2/2)

| Part No.                  | Organization<br>(word x bit) | Cycle<br>time | Clock<br>frequency | Operating Ambient<br>Temperature | Package                                          |
|---------------------------|------------------------------|---------------|--------------------|----------------------------------|--------------------------------------------------|
| μPD44325092BF5-E33Y-FQ1-A | 4M x 9                       | 3.3ns         | 300MHz             | Ta = -40 to 85°C                 | 165-pin<br>PLASTIC BGA<br>(15 x 17)<br>Lead-free |
| μPD44325092BF5-E35Y-FQ1-A |                              | 3.5ns         | 287MHz             |                                  |                                                  |
| μPD44325092BF5-E40Y-FQ1-A |                              | 4.0ns         | 250MHz             |                                  |                                                  |
| μPD44325092BF5-E50Y-FQ1-A |                              | 5.0ns         | 200MHz             |                                  |                                                  |
| μPD44325182BF5-E33Y-FQ1-A | 2M x 18                      | 3.3ns         | 300MHz             |                                  |                                                  |
| μPD44325182BF5-E35Y-FQ1-A |                              | 3.5ns         | 287MHz             |                                  |                                                  |
| μPD44325182BF5-E40Y-FQ1-A |                              | 4.0ns         | 250MHz             |                                  |                                                  |
| μPD44325182BF5-E50Y-FQ1-A |                              | 5.0ns         | 200MHz             |                                  |                                                  |
| μPD44325362BF5-E33Y-FQ1-A | 1M x 36                      | 3.3ns         | 300MHz             |                                  |                                                  |
| μPD44325362BF5-E35Y-FQ1-A |                              | 3.5ns         | 287MHz             |                                  |                                                  |
| μPD44325362BF5-E40Y-FQ1-A |                              | 4.0ns         | 250MHz             |                                  |                                                  |
| μPD44325362BF5-E50Y-FQ1-A |                              | 5.0ns         | 200MHz             |                                  |                                                  |
| μPD44325092BF5-E33Y-FQ1   | 4M x 9                       | 3.3ns         | 300MHz             | Ta = -40 to 85°C                 | 165-pin<br>PLASTIC BGA<br>(15 x 17)<br>Lead      |
| μPD44325092BF5-E35Y-FQ1   |                              | 3.5ns         | 287MHz             |                                  |                                                  |
| μPD44325092BF5-E40Y-FQ1   |                              | 4.0ns         | 250MHz             |                                  |                                                  |
| μPD44325092BF5-E50Y-FQ1   |                              | 5.0ns         | 200MHz             |                                  |                                                  |
| μPD44325182BF5-E33Y-FQ1   | 2M x 18                      | 3.3ns         | 300MHz             |                                  |                                                  |
| μPD44325182BF5-E35Y-FQ1   |                              | 3.5ns         | 287MHz             |                                  |                                                  |
| μPD44325182BF5-E40Y-FQ1   |                              | 4.0ns         | 250MHz             |                                  |                                                  |
| μPD44325182BF5-E50Y-FQ1   |                              | 5.0ns         | 200MHz             |                                  |                                                  |
| μPD44325362BF5-E33Y-FQ1   | 1M x 36                      | 3.3ns         | 300MHz             |                                  |                                                  |
| μPD44325362BF5-E35Y-FQ1   |                              | 3.5ns         | 287MHz             |                                  |                                                  |
| μPD44325362BF5-E40Y-FQ1   |                              | 4.0ns         | 250MHz             |                                  |                                                  |
| μPD44325362BF5-E50Y-FQ1   |                              | 5.0ns         | 200MHz             |                                  |                                                  |

## Pin Arrangement

165-pin PLASTIC BGA (15 x 17)

(Top View)

[μPD44325092B]

4M x 9

|   | 1    | 2                    | 3                 | 4                 | 5               | 6               | 7               | 8                 | 9                 | 10               | 11  |
|---|------|----------------------|-------------------|-------------------|-----------------|-----------------|-----------------|-------------------|-------------------|------------------|-----|
| A | CQ#  | V <sub>SS</sub> /72M | A                 | W#                | NC              | K#              | NC/144M         | R#                | A                 | A                | CQ  |
| B | NC   | NC                   | NC                | A                 | NC/288M         | K               | BW0#            | A                 | NC                | NC               | Q4  |
| C | NC   | NC                   | NC                | V <sub>SS</sub>   | A               | A               | A               | V <sub>SS</sub>   | NC                | NC               | D4  |
| D | NC   | D5                   | NC                | V <sub>SS</sub>   | V <sub>SS</sub> | V <sub>SS</sub> | V <sub>SS</sub> | V <sub>SS</sub>   | NC                | NC               | NC  |
| E | NC   | NC                   | Q5                | V <sub>DD</sub> Q | V <sub>SS</sub> | V <sub>SS</sub> | V <sub>SS</sub> | V <sub>DD</sub> Q | NC                | D3               | Q3  |
| F | NC   | NC                   | NC                | V <sub>DD</sub> Q | V <sub>DD</sub> | V <sub>SS</sub> | V <sub>DD</sub> | V <sub>DD</sub> Q | NC                | NC               | NC  |
| G | NC   | D6                   | Q6                | V <sub>DD</sub> Q | V <sub>DD</sub> | V <sub>SS</sub> | V <sub>DD</sub> | V <sub>DD</sub> Q | NC                | NC               | NC  |
| H | DLL# | V <sub>REF</sub>     | V <sub>DD</sub> Q | V <sub>DD</sub> Q | V <sub>DD</sub> | V <sub>SS</sub> | V <sub>DD</sub> | V <sub>DD</sub> Q | V <sub>DD</sub> Q | V <sub>REF</sub> | ZQ  |
| J | NC   | NC                   | NC                | V <sub>DD</sub> Q | V <sub>DD</sub> | V <sub>SS</sub> | V <sub>DD</sub> | V <sub>DD</sub> Q | NC                | Q2               | D2  |
| K | NC   | NC                   | NC                | V <sub>DD</sub> Q | V <sub>DD</sub> | V <sub>SS</sub> | V <sub>DD</sub> | V <sub>DD</sub> Q | NC                | NC               | NC  |
| L | NC   | Q7                   | D7                | V <sub>DD</sub> Q | V <sub>SS</sub> | V <sub>SS</sub> | V <sub>SS</sub> | V <sub>DD</sub> Q | NC                | NC               | Q1  |
| M | NC   | NC                   | NC                | V <sub>SS</sub>   | V <sub>SS</sub> | V <sub>SS</sub> | V <sub>SS</sub> | V <sub>SS</sub>   | NC                | NC               | D1  |
| N | NC   | D8                   | NC                | V <sub>SS</sub>   | A               | A               | A               | V <sub>SS</sub>   | NC                | NC               | NC  |
| P | NC   | NC                   | Q8                | A                 | A               | C               | A               | A                 | NC                | D0               | Q0  |
| R | TDO  | TCK                  | A                 | A                 | A               | C#              | A               | A                 | A                 | TMS              | TDI |

|          |                             |                   |                              |
|----------|-----------------------------|-------------------|------------------------------|
| A        | : Address inputs            | TMS               | : IEEE 1149.1 Test input     |
| D0 to D8 | : Data inputs               | TDI               | : IEEE 1149.1 Test input     |
| Q0 to Q8 | : Data outputs              | TCK               | : IEEE 1149.1 Clock input    |
| R#       | : Read input                | TDO               | : IEEE 1149.1 Test output    |
| W#       | : Write input               | V <sub>REF</sub>  | : HSTL input reference input |
| BW0#     | : Byte Write data select    | V <sub>DD</sub>   | : Power Supply               |
| K, K#    | : Input clock               | V <sub>DD</sub> Q | : Power Supply               |
| C, C#    | : Output clock              | V <sub>SS</sub>   | : Ground                     |
| CQ, CQ#  | : Echo clock                | NC                | : No connection              |
| ZQ       | : Output impedance matching | NC/xxM            | : Expansion address for xxMb |
| DLL#     | : PLL disable               |                   |                              |

**Remarks 1.** xxx# indicates active LOW.

2. Refer to **Package Dimensions** for the index mark.

3. 2A, 7A and 5B are expansion addresses : 2A for 72Mb  
: 2A and 7A for 144Mb  
: 2A, 7A and 5B for 288Mb

2A of this product can also be used as NC.

## Pin Arrangement

165-pin PLASTIC BGA (15 x 17)

(Top View)

[μPD44325182B]

2M x 18

|   | 1    | 2                     | 3                | 4                | 5               | 6               | 7               | 8                | 9                | 10                   | 11  |
|---|------|-----------------------|------------------|------------------|-----------------|-----------------|-----------------|------------------|------------------|----------------------|-----|
| A | CQ#  | V <sub>SS</sub> /144M | A                | W#               | BW1#            | K#              | NC/288M         | R#               | A                | V <sub>SS</sub> /72M | CQ  |
| B | NC   | Q9                    | D9               | A                | NC              | K               | BW0#            | A                | NC               | NC                   | Q8  |
| C | NC   | NC                    | D10              | V <sub>SS</sub>  | A               | A               | A               | V <sub>SS</sub>  | NC               | Q7                   | D8  |
| D | NC   | D11                   | Q10              | V <sub>SS</sub>  | V <sub>SS</sub> | V <sub>SS</sub> | V <sub>SS</sub> | V <sub>SS</sub>  | NC               | NC                   | D7  |
| E | NC   | NC                    | Q11              | V <sub>DDQ</sub> | V <sub>SS</sub> | V <sub>SS</sub> | V <sub>SS</sub> | V <sub>DDQ</sub> | NC               | D6                   | Q6  |
| F | NC   | Q12                   | D12              | V <sub>DDQ</sub> | V <sub>DD</sub> | V <sub>SS</sub> | V <sub>DD</sub> | V <sub>DDQ</sub> | NC               | NC                   | Q5  |
| G | NC   | D13                   | Q13              | V <sub>DDQ</sub> | V <sub>DD</sub> | V <sub>SS</sub> | V <sub>DD</sub> | V <sub>DDQ</sub> | NC               | NC                   | D5  |
| H | DLL# | V <sub>REF</sub>      | V <sub>DDQ</sub> | V <sub>DDQ</sub> | V <sub>DD</sub> | V <sub>SS</sub> | V <sub>DD</sub> | V <sub>DDQ</sub> | V <sub>DDQ</sub> | V <sub>REF</sub>     | ZQ  |
| J | NC   | NC                    | D14              | V <sub>DDQ</sub> | V <sub>DD</sub> | V <sub>SS</sub> | V <sub>DD</sub> | V <sub>DDQ</sub> | NC               | Q4                   | D4  |
| K | NC   | NC                    | Q14              | V <sub>DDQ</sub> | V <sub>DD</sub> | V <sub>SS</sub> | V <sub>DD</sub> | V <sub>DDQ</sub> | NC               | D3                   | Q3  |
| L | NC   | Q15                   | D15              | V <sub>DDQ</sub> | V <sub>SS</sub> | V <sub>SS</sub> | V <sub>SS</sub> | V <sub>DDQ</sub> | NC               | NC                   | Q2  |
| M | NC   | NC                    | D16              | V <sub>SS</sub>  | V <sub>SS</sub> | V <sub>SS</sub> | V <sub>SS</sub> | V <sub>SS</sub>  | NC               | Q1                   | D2  |
| N | NC   | D17                   | Q16              | V <sub>SS</sub>  | A               | A               | A               | V <sub>SS</sub>  | NC               | NC                   | D1  |
| P | NC   | NC                    | Q17              | A                | A               | C               | A               | A                | NC               | D0                   | Q0  |
| R | TDO  | TCK                   | A                | A                | A               | C#              | A               | A                | A                | TMS                  | TDI |

|            |                             |                  |                              |
|------------|-----------------------------|------------------|------------------------------|
| A          | : Address inputs            | TMS              | : IEEE 1149.1 Test input     |
| D0 to D17  | : Data inputs               | TDI              | : IEEE 1149.1 Test input     |
| Q0 to Q17  | : Data outputs              | TCK              | : IEEE 1149.1 Clock input    |
| R#         | : Read input                | TDO              | : IEEE 1149.1 Test output    |
| W#         | : Write input               | V <sub>REF</sub> | : HSTL input reference input |
| BW0#, BW1# | : Byte Write data select    | V <sub>DD</sub>  | : Power Supply               |
| K, K#      | : Input clock               | V <sub>DDQ</sub> | : Power Supply               |
| C, C#      | : Output clock              | V <sub>SS</sub>  | : Ground                     |
| CQ, CQ#    | : Echo clock                | NC               | : No connection              |
| ZQ         | : Output impedance matching | NC/xxM           | : Expansion address for xxMb |
| DLL#       | : PLL disable               |                  |                              |

**Remarks 1.** xxx# indicates active LOW.

2. Refer to **Package Dimensions** for the index mark.

3. 2A, 7A and 10A are expansion addresses : 10A for 72Mb  
: 10A and 2A for 144Mb  
: 10A, 2A and 7A for 288Mb

2A and 10A of this product can also be used as NC.

## Pin Arrangement

165-pin PLASTIC BGA (15 x 17)

(Top View)

[μPD44325362B]

1M x 36

|   | 1    | 2        | 3      | 4    | 5    | 6   | 7    | 8    | 9    | 10       | 11  |
|---|------|----------|--------|------|------|-----|------|------|------|----------|-----|
| A | CQ#  | Vss/288M | NC/72M | W#   | BW2# | K#  | BW1# | R#   | A    | Vss/144M | CQ  |
| B | Q27  | Q18      | D18    | A    | BW3# | K   | BW0# | A    | D17  | Q17      | Q8  |
| C | D27  | Q28      | D19    | Vss  | A    | A   | A    | Vss  | D16  | Q7       | D8  |
| D | D28  | D20      | Q19    | Vss  | Vss  | Vss | Vss  | Vss  | Q16  | D15      | D7  |
| E | Q29  | D29      | Q20    | VDDQ | Vss  | Vss | Vss  | VDDQ | Q15  | D6       | Q6  |
| F | Q30  | Q21      | D21    | VDDQ | VDD  | Vss | VDD  | VDDQ | D14  | Q14      | Q5  |
| G | D30  | D22      | Q22    | VDDQ | VDD  | Vss | VDD  | VDDQ | Q13  | D13      | D5  |
| H | DLL# | VREF     | VDDQ   | VDDQ | VDD  | Vss | VDD  | VDDQ | VDDQ | VREF     | ZQ  |
| J | D31  | Q31      | D23    | VDDQ | VDD  | Vss | VDD  | VDDQ | D12  | Q4       | D4  |
| K | Q32  | D32      | Q23    | VDDQ | VDD  | Vss | VDD  | VDDQ | Q12  | D3       | Q3  |
| L | Q33  | Q24      | D24    | VDDQ | Vss  | Vss | Vss  | VDDQ | D11  | Q11      | Q2  |
| M | D33  | Q34      | D25    | Vss  | Vss  | Vss | Vss  | Vss  | D10  | Q1       | D2  |
| N | D34  | D26      | Q25    | Vss  | A    | A   | A    | Vss  | Q10  | D9       | D1  |
| P | Q35  | D35      | Q26    | A    | A    | C   | A    | A    | Q9   | D0       | Q0  |
| R | TDO  | TCK      | A      | A    | A    | C#  | A    | A    | A    | TMS      | TDI |

|              |                             |        |                              |
|--------------|-----------------------------|--------|------------------------------|
| A            | : Address inputs            | TMS    | : IEEE 1149.1 Test input     |
| D0 to D35    | : Data inputs               | TDI    | : IEEE 1149.1 Test input     |
| Q0 to Q35    | : Data outputs              | TCK    | : IEEE 1149.1 Clock input    |
| R#           | : Read input                | TDO    | : IEEE 1149.1 Test output    |
| W#           | : Write input               | VREF   | : HSTL input reference input |
| BW0# to BW3# | : Byte Write data select    | VDD    | : Power Supply               |
| K, K#        | : Input clock               | VDDQ   | : Power Supply               |
| C, C#        | : Output clock              | Vss    | : Ground                     |
| CQ, CQ#      | : Echo clock                | NC     | : No connection              |
| ZQ           | : Output impedance matching | NC/xxM | : Expansion address for xxMb |
| DLL#         | : PLL disable               |        |                              |

**Remarks 1.** xxx# indicates active LOW.

2. Refer to **Package Dimensions** for the index mark.

3. 2A, 3A and 10A are expansion addresses : 3A for 72Mb

: 3A and 10A for 144Mb

: 3A, 10A and 2A for 288Mb

2A and 10A of this product can also be used as NC.

## Pin Description

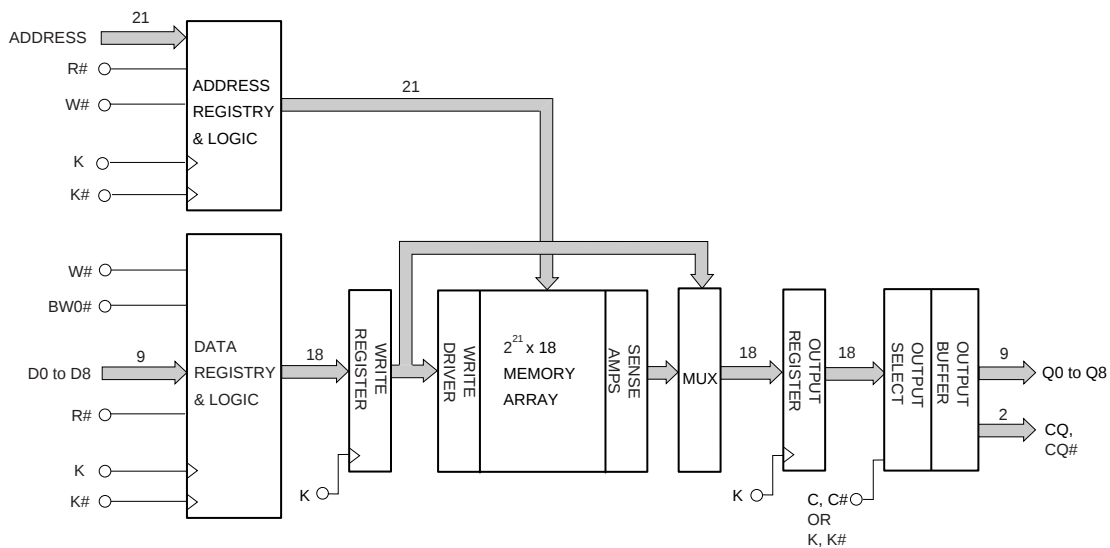
(1/2)

| Symbol    | Type   | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
|-----------|--------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| A         | Input  | Synchronous Address Inputs: These inputs are registered and must meet the setup and hold times around the rising edge of K for READ cycles and must meet the setup and hold times around the rising edge of K# for WRITE cycles. All transactions operate on a burst of two words (one clock period of bus activity). These inputs are ignored when device is deselected, i.e., NOP (R# = W# = HIGH).                                                                                                 |
| D0 to Dxx | Input  | Synchronous Data Inputs: Input data must meet setup and hold times around the rising edges of K and K# during WRITE operations. See <b>Pin Arrangement</b> for ball site location of individual signals.<br>x9 device uses D0 to D8.<br>x18 device uses D0 to D17.<br>x36 device uses D0 to D35.                                                                                                                                                                                                      |
| Q0 to Qxx | Output | Synchronous Data Outputs: Output data is synchronized to the respective C and C# or to K and K# rising edges if C and C# are tied HIGH. Data is output in synchronization with C and C# (or K and K#), depending on the R# command. See <b>Pin Arrangement</b> for ball site location of individual signals.<br>x9 device uses Q0 to Q8.<br>x18 device uses Q0 to Q17.<br>x36 device uses Q0 to Q35.                                                                                                  |
| R#        | Input  | Synchronous Read: When LOW this input causes the address inputs to be registered and a READ cycle to be initiated. This input must meet setup and hold times around the rising edge of K.                                                                                                                                                                                                                                                                                                             |
| W#        | Input  | Synchronous Write: When LOW this input causes the address inputs to be registered and a WRITE cycle to be initiated. This input must meet setup and hold times around the rising edge of K.                                                                                                                                                                                                                                                                                                           |
| BWx#      | Input  | Synchronous Byte Writes: When LOW these inputs cause their respective byte to be registered and written during WRITE cycles. These signals must meet setup and hold times around the rising edges of K and K# for each of the two rising edges comprising the WRITE cycle. See <b>Pin Arrangement</b> for signal to data relationships.<br>x9 device uses BW0#.<br>x18 device uses BW0#, BW1#.<br>x36 device uses BW0# to BW3#.<br>See <b>Byte Write Operation</b> for relation between BWx# and Dxx. |
| K, K#     | Input  | Input Clock: A READ address and control input signal are input in synchronization with the rising edge of K and a WRITE address is input in synchronization with the rising edge of K#. Input data is input in synchronization with the rising edge of K and K#. K# is ideally 180 degrees out of phase with K. All synchronous inputs must meet setup and hold times around the clock rising edges.                                                                                                  |
| C, C#     | Input  | Output Clock: This clock pair provides a user controlled means of tuning device output data. The rising edge of C# is used as the output timing reference for first output data. The rising edge of C is used as the output reference for second output data. Ideally, C# is 180 degrees out of phase with C. When use of K and K# as the reference instead of C and C#, then fixed C and C# to HIGH. Operation cannot be guaranteed unless C and C# are fixed to HIGH (i.e. toggle of C and C#).     |

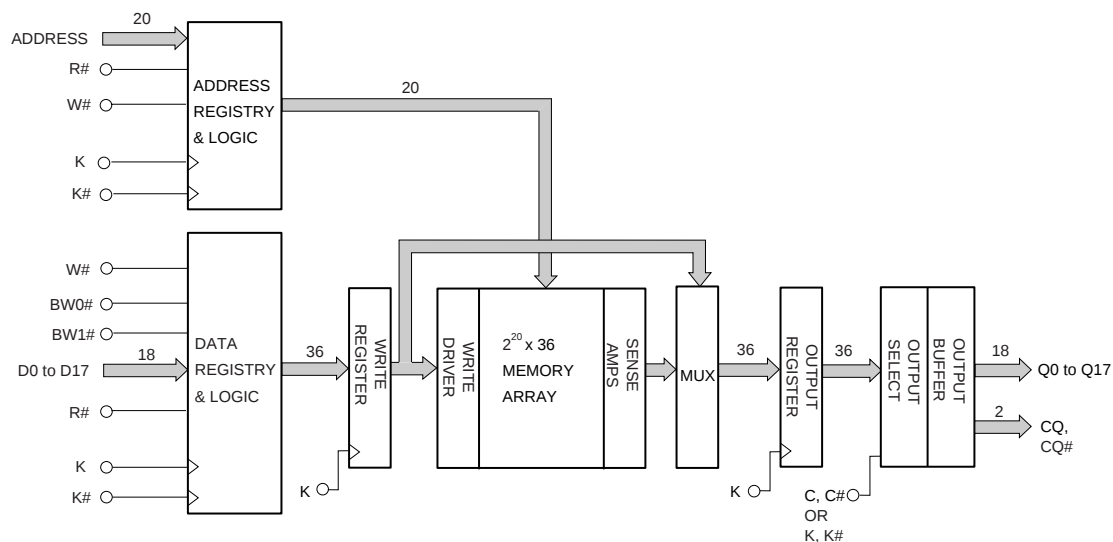
| Symbol     | Type   | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
|------------|--------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| CQ, CQ#    | Output | Synchronous Echo Clock Outputs. The rising edges of these outputs are tightly matched to the synchronous data outputs and can be used as a data valid indication. These signals run freely and do not stop when Q tristates. If C and C# are stopped (if K and K# are stopped in the single clock mode), CQ and CQ# will also stop.                                                                                                                                                                                                                                                              |
| ZQ         | Input  | Output Impedance Matching Input: This input is used to tune the device outputs to the system data bus impedance. Q, CQ and CQ# output impedance are set to $0.2 \times RQ$ , where RQ is a resistor from this bump to ground. The output impedance can be minimized by directly connect ZQ to VDDQ. This pin cannot be connected directly to GND or left unconnected. The output impedance is adjusted every 20 μs upon power-up to account for drifts in supply voltage and temperature. After replacement for a resistor, the new output impedance is reset by implementing power-on sequence. |
| DLL#       | Input  | PLL Disable: When debugging the system or board, the operation can be performed at a clock frequency slower than TKHKH (MAX.) without the PLL circuit being used, if DLL# = LOW. The AC/DC characteristics cannot be guaranteed. For normal operation, DLL# must be HIGH and it can be connected to VDDQ through a 10 kΩ or less resistor.                                                                                                                                                                                                                                                       |
| TMS<br>TDI | Input  | IEEE 1149.1 Test Inputs: 1.8 V I/O level. These balls may be left Not Connected if the JTAG function is not used in the circuit.                                                                                                                                                                                                                                                                                                                                                                                                                                                                 |
| TCK        | Input  | IEEE 1149.1 Clock Input: 1.8 V I/O level. This pin must be tied to VSS if the JTAG function is not used in the circuit.                                                                                                                                                                                                                                                                                                                                                                                                                                                                          |
| TDO        | Output | IEEE 1149.1 Test Output: 1.8 V I/O level.<br>When providing any external voltage to TDO signal, it is recommended to pull up to VDD.                                                                                                                                                                                                                                                                                                                                                                                                                                                             |
| VREF       | –      | HSTL Input Reference Voltage: Nominally VDDQ/2. Provides a reference voltage for the input buffers.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                              |
| VDD        | Supply | Power Supply: 1.8 V nominal. See <b>Recommended DC Operating Conditions</b> and <b>DC Characteristics</b> for range.                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |
| VDDQ       | Supply | Power Supply: Isolated Output Buffer Supply. Nominally 1.5 V. 1.8 V is also permissible. See <b>Recommended DC Operating Conditions</b> and <b>DC Characteristics</b> for range.                                                                                                                                                                                                                                                                                                                                                                                                                 |
| VSS        | Supply | Power Supply: Ground                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                             |
| NC         | –      | No Connect: These signals are not connected internally.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                          |

## Block Diagram

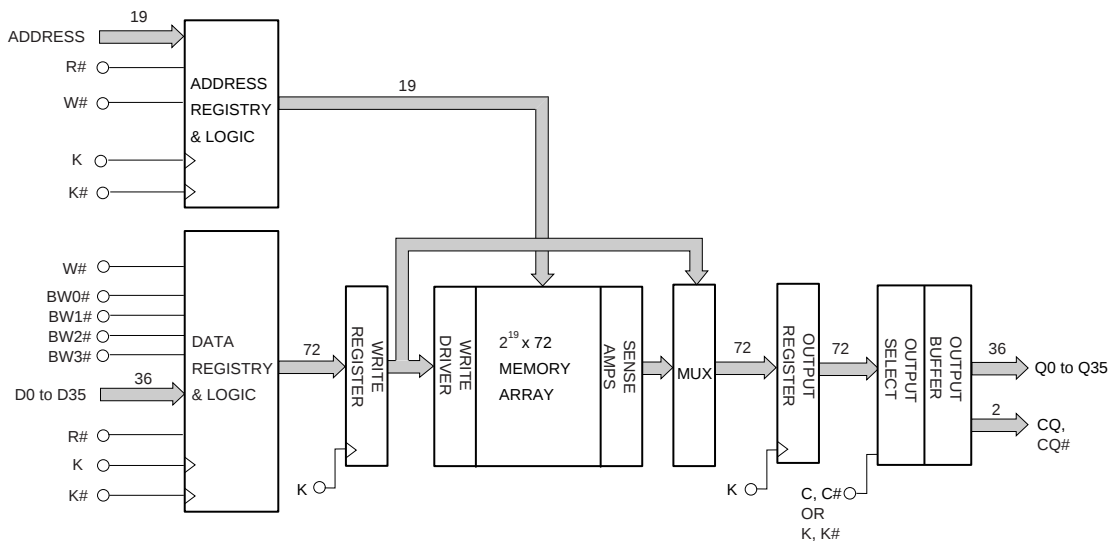
### [μPD44325092B]



### [μPD44325182B]



### [μPD44325362B]



## Power-On Sequence in QDR II SRAM

QDR II SRAMs must be powered up and initialized in a predefined manner to prevent undefined operations.

The following timing charts show the recommended power-on sequence.

The following power-up supply voltage application is recommended:  $V_{SS}$ ,  $V_{DD}$ ,  $V_{DDQ}$ ,  $V_{REF}$ , then  $V_{IN}$ .  $V_{DD}$  and  $V_{DDQ}$  can be applied simultaneously, as long as  $V_{DDQ}$  does not exceed  $V_{DD}$  by more than 0.5 V during power-up. The following power-down supply voltage removal sequence is recommended:  $V_{IN}$ ,  $V_{REF}$ ,  $V_{DDQ}$ ,  $V_{DD}$ ,  $V_{SS}$ .  $V_{DD}$  and  $V_{DDQ}$  can be removed simultaneously, as long as  $V_{DDQ}$  does not exceed  $V_{DD}$  by more than 0.5 V during power-down.

### Power-On Sequence

Apply power and tie  $DLL\#$  to HIGH.

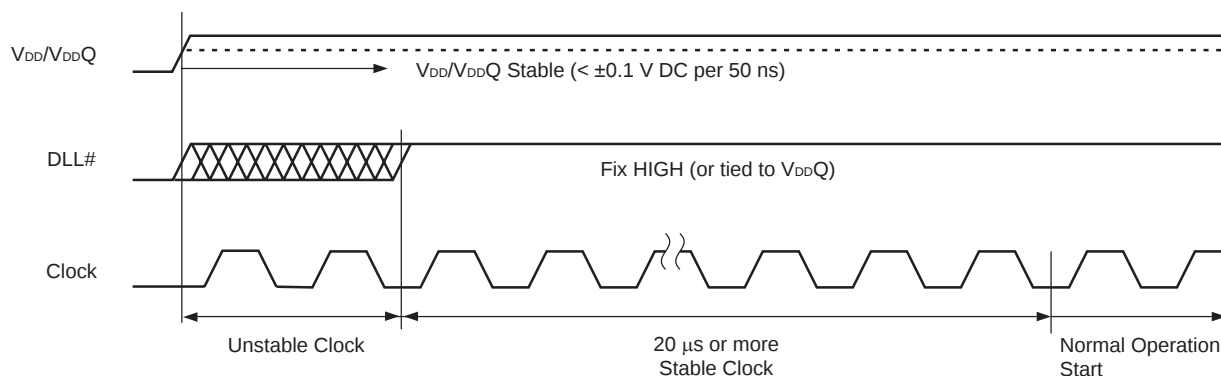
- Apply  $V_{DD}$  before  $V_{DDQ}$ .
- Apply  $V_{DDQ}$  before  $V_{REF}$  or at the same time as  $V_{REF}$ .

Provide stable clock for more than 20  $\mu s$  to lock the PLL.

### PLL Constraints

The PLL uses K clock as its synchronizing input and the input should have low phase jitter which is specified as TKC var. The PLL can cover 120 MHz as the lowest frequency. If the input clock is unstable and the PLL is enabled, then the PLL may lock onto an undesired clock frequency.

### Power-On Waveforms



**Truth Table**

| Operation                                                                            | CLK     | R# | W# | D or Q            |           |           |
|--------------------------------------------------------------------------------------|---------|----|----|-------------------|-----------|-----------|
| WRITE cycle<br>Load address, input write data on<br>consecutive K and K# rising edge | L → H   | ×  | L  | Data in           |           |           |
|                                                                                      |         |    |    | Input data        | DA (A+0)  | DA (A+1)  |
|                                                                                      |         |    |    | Input clock       | K( t ) ↑  | K#( t ) ↑ |
| READ cycle<br>Load address, output data on<br>consecutive C and C# rising edge       | L → H   | L  | ×  | Data out          |           |           |
|                                                                                      |         |    |    | Output data       | QA (A+0)  | QA (A+1)  |
|                                                                                      |         |    |    | Output clock      | C#(t+1) ↑ | C(t+2) ↑  |
| NOP (No operation)                                                                   | L → H   | H  | H  | D = ×, Q = High-Z |           |           |
| Clock stop                                                                           | Stopped | ×  | ×  | Previous state    |           |           |

**Remarks 1.** H : HIGH, L : LOW, × : don't care, ↑ : rising edge.

2. Data inputs are registered at K and K# rising edges. Data outputs are delivered at C and C# rising edges except if C and C# are HIGH then Data outputs are delivered at K and K# rising edges.
3. All control inputs in the truth table must meet setup/hold times around the rising edge (LOW to HIGH) of K. All control inputs are registered during the rising edge of K.
4. This device contains circuitry that ensure the outputs to be in high impedance during power-up.
5. Refer to state diagram and timing diagrams for clarification.
6. It is recommended that K = K# = C = C# when clock is stopped. This is not essential but permits most rapid restart by overcoming transmission line charging symmetrically.

## Byte Write Operation

### [μPD44325092B]

| Operation      | K     | K#    | BW0# |
|----------------|-------|-------|------|
| Write D0 to D8 | L → H | –     | 0    |
|                | –     | L → H | 0    |
| Write nothing  | L → H | –     | 1    |
|                | –     | L → H | 1    |

**Remarks 1.** H : HIGH, L : LOW, → : rising edge.

2. Assumes a WRITE cycle was initiated. BW0# can be altered for any portion of the BURST WRITE operation provided that the setup and hold requirements are satisfied.

### [μPD44325182B]

| Operation       | K     | K#    | BW0# | BW1# |
|-----------------|-------|-------|------|------|
| Write D0 to D17 | L → H | –     | 0    | 0    |
|                 | –     | L → H | 0    | 0    |
| Write D0 to D8  | L → H | –     | 0    | 1    |
|                 | –     | L → H | 0    | 1    |
| Write D9 to D17 | L → H | –     | 1    | 0    |
|                 | –     | L → H | 1    | 0    |
| Write nothing   | L → H | –     | 1    | 1    |
|                 | –     | L → H | 1    | 1    |

**Remarks 1.** H : HIGH, L : LOW, → : rising edge.

2. Assumes a WRITE cycle was initiated. BW0# and BW1# can be altered for any portion of the BURST WRITE operation provided that the setup and hold requirements are satisfied.

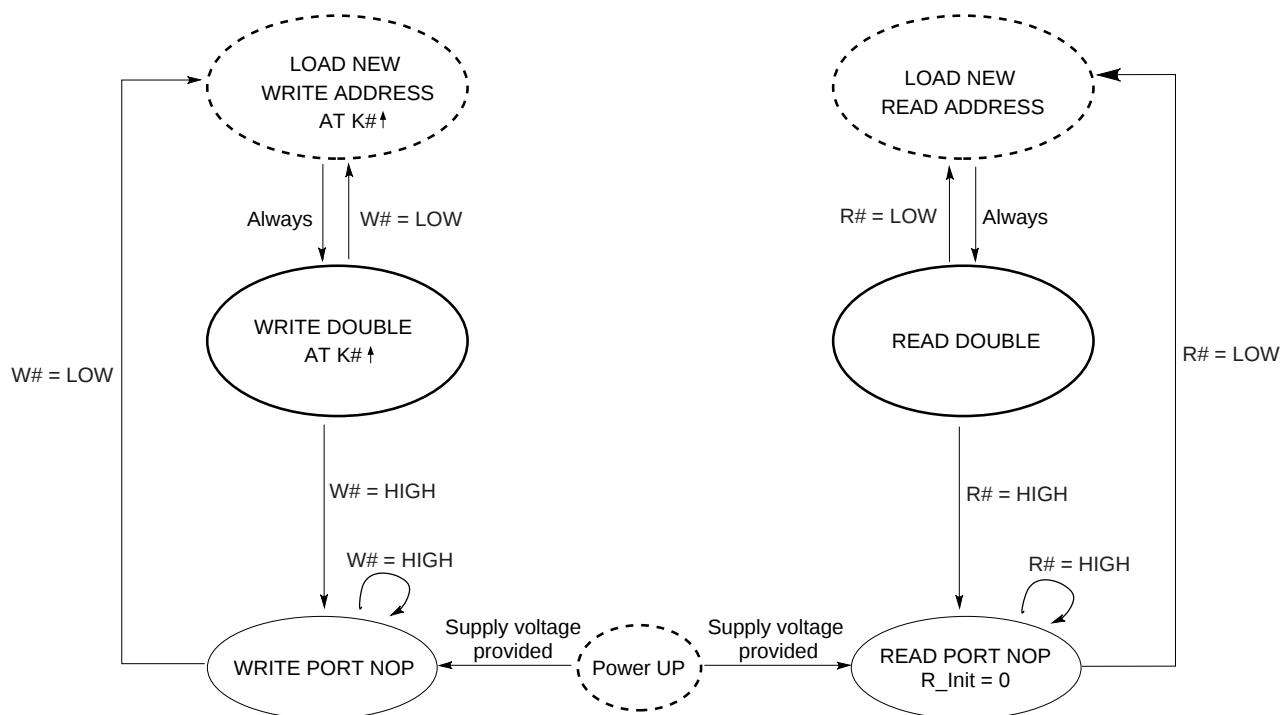
### [μPD44325362B]

| Operation        | K     | K#    | BW0# | BW1# | BW2# | BW3# |
|------------------|-------|-------|------|------|------|------|
| Write D0 to D35  | L → H | –     | 0    | 0    | 0    | 0    |
|                  | –     | L → H | 0    | 0    | 0    | 0    |
| Write D0 to D8   | L → H | –     | 0    | 1    | 1    | 1    |
|                  | –     | L → H | 0    | 1    | 1    | 1    |
| Write D9 to D17  | L → H | –     | 1    | 0    | 1    | 1    |
|                  | –     | L → H | 1    | 0    | 1    | 1    |
| Write D18 to D26 | L → H | –     | 1    | 1    | 0    | 1    |
|                  | –     | L → H | 1    | 1    | 0    | 1    |
| Write D27 to D35 | L → H | –     | 1    | 1    | 1    | 0    |
|                  | –     | L → H | 1    | 1    | 1    | 0    |
| Write nothing    | L → H | –     | 1    | 1    | 1    | 1    |
|                  | –     | L → H | 1    | 1    | 1    | 1    |

**Remarks 1.** H : HIGH, L : LOW, → : rising edge.

2. Assumes a WRITE cycle was initiated. BW0# to BW3# can be altered for any portion of the BURST WRITE operation provided that the setup and hold requirements are satisfied.

## Bus Cycle State Diagram



**Remarks 1.** The address is concatenated with 1 additional internal LSB to facilitate burst operation.

The address order is always fixed as: xxx...xxx+0, xxx...xxx+1.

Bus cycle is terminated at the end of this sequence (burst count = 2).

2. Read and write state machines can be active simultaneously.

3. State machine control timing sequence is controlled by K.

## Electrical Characteristics

### Absolute Maximum Ratings

| Parameter                     | Symbol    | Conditions    | Rating                             | Unit |
|-------------------------------|-----------|---------------|------------------------------------|------|
| Supply voltage                | $V_{DD}$  |               | -0.5 to +2.5                       | V    |
| Output supply voltage         | $V_{DDQ}$ |               | -0.5 to $V_{DD}$                   | V    |
| Input voltage                 | $V_{IN}$  |               | -0.5 to $V_{DD}+0.5$ (2.5 V MAX.)  | V    |
| Input / Output voltage        | $V_{I/O}$ |               | -0.5 to $V_{DDQ}+0.5$ (2.5 V MAX.) | V    |
| Operating ambient temperature | $T_A$     | (E** series)  | 0 to 70                            | °C   |
|                               |           | (E**Y series) | -40 to 85                          |      |
| Storage temperature           | $T_{stg}$ |               | -55 to +125                        | °C   |

**Caution** Exposing the device to stress above those listed in Absolute Maximum Ratings could cause permanent damage. The device is not meant to be operated under conditions outside the limits described in the operational section of this specification. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

### Recommended DC Operating Conditions ( $T_A = 0$ to $70^\circ\text{C}$ , $T_A = -40$ to $85^\circ\text{C}$ )

| Parameter             | Symbol       | Conditions | MIN.            | TYP. | MAX.            | Unit | Note |
|-----------------------|--------------|------------|-----------------|------|-----------------|------|------|
| Supply voltage        | $V_{DD}$     |            | 1.7             | 1.8  | 1.9             | V    |      |
| Output supply voltage | $V_{DDQ}$    |            | 1.4             |      | $V_{DD}$        | V    | 1    |
| Input HIGH voltage    | $V_{IH(DC)}$ |            | $V_{REF} + 0.1$ |      | $V_{DDQ} + 0.3$ | V    | 1, 2 |
| Input LOW voltage     | $V_{IL(DC)}$ |            | -0.3            |      | $V_{REF} - 0.1$ | V    | 1, 2 |
| Clock input voltage   | $V_{IN}$     |            | -0.3            |      | $V_{DDQ} + 0.3$ | V    | 1, 2 |
| Reference voltage     | $V_{REF}$    |            | 0.68            |      | 0.95            | V    |      |

**Notes** 1. During normal operation,  $V_{DDQ}$  must not exceed  $V_{DD}$ .

2. Power-up:  $V_{IH} \leq V_{DDQ} + 0.3$  V and  $V_{DD} \leq 1.7$  V and  $V_{DDQ} \leq 1.4$  V for  $t \leq 200$  ms

### Recommended AC Operating Conditions ( $T_A = 0$ to $70^\circ\text{C}$ , $T_A = -40$ to $85^\circ\text{C}$ )

| Parameter          | Symbol       | Conditions | MIN.            | MAX.            | Unit | Note |
|--------------------|--------------|------------|-----------------|-----------------|------|------|
| Input HIGH voltage | $V_{IH(AC)}$ |            | $V_{REF} + 0.2$ |                 | V    | 1    |
| Input LOW voltage  | $V_{IL(AC)}$ |            |                 | $V_{REF} - 0.2$ | V    | 1    |

**Note** 1. Overshoot:  $V_{IH(AC)} \leq V_{DD} + 0.7$  V (2.5 V MAX.) for  $t \leq TKHKH/2$

Undershoot:  $V_{IL(AC)} \geq -0.5$  V for  $t \leq TKHKH/2$

Control input signals may not have pulse widths less than TKHKL (MIN.) or operate at cycle rates less than TKHKH (MIN.).

DC Characteristics 1 (T<sub>A</sub> = 0 to 70°C, V<sub>DD</sub> = 1.8 ± 0.1 V)

| Parameter                                              | Symbol   | Test condition                                                           | MIN.                     | MAX.                     |     |     | Unit | Note |
|--------------------------------------------------------|----------|--------------------------------------------------------------------------|--------------------------|--------------------------|-----|-----|------|------|
|                                                        |          |                                                                          |                          | x9                       | x18 | x36 |      |      |
| Input leakage current                                  | ILI      |                                                                          | -2                       | +2                       |     |     | μA   |      |
| I/O leakage current                                    | ILO      |                                                                          | -2                       | +2                       |     |     | μA   |      |
| Operating supply current<br>(Read cycle / Write cycle) | IDD      | VIN ≤ VIL or VIN ≥ VIH,<br>II/O = 0 mA,<br>Cycle = MAX.                  | -E33                     | 570                      | 690 | 770 | mA   |      |
|                                                        |          |                                                                          | -E35                     | 550                      | 660 | 750 |      |      |
|                                                        |          |                                                                          | -E40                     | 510                      | 610 | 690 |      |      |
|                                                        |          |                                                                          | -E50                     | 440                      | 530 | 590 |      |      |
| Standby supply current<br>(NOP)                        | ISB1     | VIN ≤ VIL or VIN ≥ VIH,<br>II/O = 0 mA,<br>Cycle = MAX.<br>Inputs static | -E33                     | 310                      | 320 | 340 | mA   |      |
|                                                        |          |                                                                          | -E35                     | 310                      | 320 | 340 |      |      |
|                                                        |          |                                                                          | -E40                     | 300                      | 310 | 330 |      |      |
|                                                        |          |                                                                          | -E50                     | 290                      | 300 | 320 |      |      |
| Output HIGH voltage                                    | VOH(Low) | I <sub>OH</sub>   ≤ 0.1 mA                                               | V <sub>DDQ</sub> -0.2    | V <sub>DDQ</sub>         |     |     |      |      |
|                                                        | VOH      | Note1                                                                    | V <sub>DDQ</sub> /2-0.12 | V <sub>DDQ</sub> /2+0.12 |     |     |      |      |
| Output LOW voltage                                     | VOL(Low) | IOL ≤ 0.1 mA                                                             | VSS                      | 0.2                      |     |     |      |      |
|                                                        | VOL      | Note2                                                                    | V <sub>DDQ</sub> /2-0.12 | V <sub>DDQ</sub> /2+0.12 |     |     |      |      |

- Notes**
1. Outputs are impedance-controlled.  $|I_{OH}| = (V_{DDQ}/2)/(RQ/5) \pm 15\%$  for values of  $175 \Omega \leq RQ \leq 350 \Omega$ .
  2. Outputs are impedance-controlled.  $I_{OL} = (V_{DDQ}/2)/(RQ/5) \pm 15\%$  for values of  $175 \Omega \leq RQ \leq 350 \Omega$ .
  3. AC load current is higher than the shown DC values.
  4. HSTL outputs meet JEDEC HSTL Class I standards.

DC Characteristics 2 (T<sub>A</sub> = -40 to 85°C, V<sub>DD</sub> = 1.8 ± 0.1 V)

| Parameter                                              | Symbol   | Test condition                                                           | MIN.                     | MAX.                     |     |     | Unit | Note |
|--------------------------------------------------------|----------|--------------------------------------------------------------------------|--------------------------|--------------------------|-----|-----|------|------|
|                                                        |          |                                                                          |                          | x9                       | x18 | x36 |      |      |
| Input leakage current                                  | ILI      |                                                                          | -2                       | +2                       |     |     | μA   |      |
| I/O leakage current                                    | ILO      |                                                                          | -2                       | +2                       |     |     | μA   |      |
| Operating supply current<br>(Read cycle / Write cycle) | IDD      | VIN ≤ VIL or VIN ≥ VIH,<br>II/O = 0 mA,<br>Cycle = MAX.                  | -E33Y                    | 700                      | 820 | 910 | mA   |      |
|                                                        |          |                                                                          | -E35Y                    | 680                      | 790 | 890 |      |      |
|                                                        |          |                                                                          | -E40Y                    | 640                      | 740 | 830 |      |      |
|                                                        |          |                                                                          | -E50Y                    | 570                      | 670 | 730 |      |      |
| Standby supply current<br>(NOP)                        | ISB1     | VIN ≤ VIL or VIN ≥ VIH,<br>II/O = 0 mA,<br>Cycle = MAX.<br>Inputs static | -E33Y                    | 430                      | 440 | 470 | mA   |      |
|                                                        |          |                                                                          | -E35Y                    | 430                      | 440 | 470 |      |      |
|                                                        |          |                                                                          | -E40Y                    | 420                      | 430 | 460 |      |      |
|                                                        |          |                                                                          | -E50Y                    | 410                      | 420 | 450 |      |      |
| Output HIGH voltage                                    | VOH(Low) | I <sub>OH</sub>   ≤ 0.1 mA                                               | V <sub>DDQ</sub> -0.2    | V <sub>DDQ</sub>         |     |     |      |      |
|                                                        | VOH      | Note1                                                                    | V <sub>DDQ</sub> /2-0.12 | V <sub>DDQ</sub> /2+0.12 |     |     |      |      |
| Output LOW voltage                                     | VOL(Low) | I <sub>OL</sub> ≤ 0.1 mA                                                 | VSS                      | 0.2                      |     |     |      |      |
|                                                        | VOL      | Note2                                                                    | V <sub>DDQ</sub> /2-0.12 | V <sub>DDQ</sub> /2+0.12 |     |     |      |      |

- Notes**
1. Outputs are impedance-controlled. |I<sub>OH</sub>| = (V<sub>DDQ</sub>/2)/(R<sub>Q</sub>/5) ±15% for values of 175 Ω ≤ R<sub>Q</sub> ≤ 350 Ω.
  2. Outputs are impedance-controlled. I<sub>OL</sub> = (V<sub>DDQ</sub>/2)/(R<sub>Q</sub>/5) ±15% for values of 175 Ω ≤ R<sub>Q</sub> ≤ 350 Ω.
  3. AC load current is higher than the shown DC values.
  4. HSTL outputs meet JEDEC HSTL Class I standards.

**Capacitance (T<sub>A</sub> = 25°C, f = 1 MHz)**

| Parameter                                     | Symbol           | Test conditions        | MIN. | MAX. | Unit |
|-----------------------------------------------|------------------|------------------------|------|------|------|
| Input capacitance (Address, Control)          | C <sub>IN</sub>  | V <sub>IN</sub> = 0 V  |      | 5    | pF   |
| Input / Output capacitance<br>(D, Q, CQ, CQ#) | C <sub>I/O</sub> | V <sub>I/O</sub> = 0 V |      | 7    | pF   |
| Clock Input capacitance                       | C <sub>clk</sub> | V <sub>clk</sub> = 0 V |      | 6    | pF   |

**Remark** These parameters are periodically sampled and not 100% tested.

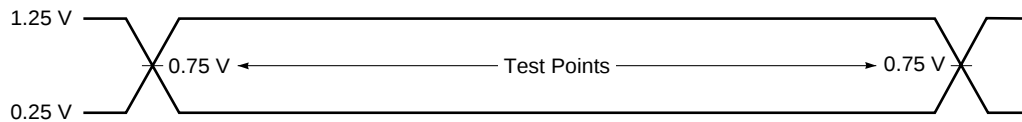
**Thermal Characteristics**

| Parameter                                                                                       | Symbol        | Substrate | Airflow | TYP. | Unit |
|-------------------------------------------------------------------------------------------------|---------------|-----------|---------|------|------|
| Thermal resistance<br>from junction to ambient air                                              | $\theta_{ja}$ | 4-layer   | 0 m/s   | 21.2 | °C/W |
|                                                                                                 |               |           | 1 m/s   | 13.4 | °C/W |
|                                                                                                 |               | 8-layer   | 0 m/s   | 20.2 | °C/W |
|                                                                                                 |               |           | 1 m/s   | 13.0 | °C/W |
| Thermal characterization parameter<br>from junction to the top center<br>of the package surface | $\psi_{jt}$   | 4-layer   | 0 m/s   | 0.02 | °C/W |
|                                                                                                 |               |           | 1 m/s   | 0.06 | °C/W |
|                                                                                                 |               | 8-layer   | 0 m/s   | 0.02 | °C/W |
|                                                                                                 |               |           | 1 m/s   | 0.05 | °C/W |
| Thermal resistance<br>from junction to case                                                     | $\theta_{jc}$ |           |         | 2.58 | °C/W |

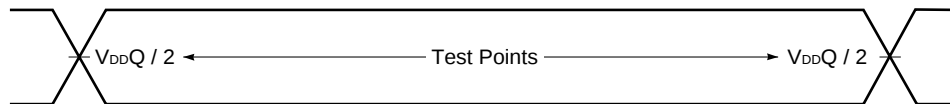
AC Characteristics ( $T_A = 0$  to  $70^\circ\text{C}$  or  $T_A = -40$  to  $85^\circ\text{C}$ ,  $V_{DD} = 1.8 \pm 0.1$  V)

AC Test Conditions ( $V_{DD} = 1.8 \pm 0.1$  V,  $V_{DDQ} = 1.4$  V to  $V_{DD}$ )

Input waveform (Rise / Fall time  $\leq 0.3$  ns)

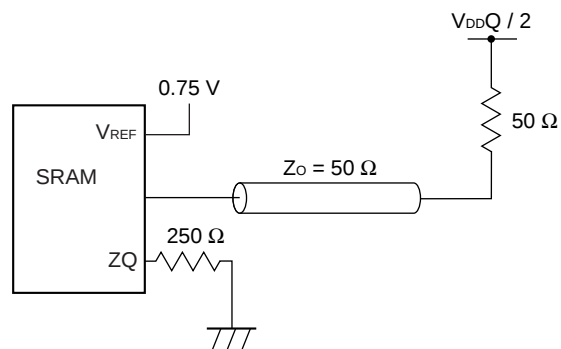


Output waveform



Output load condition

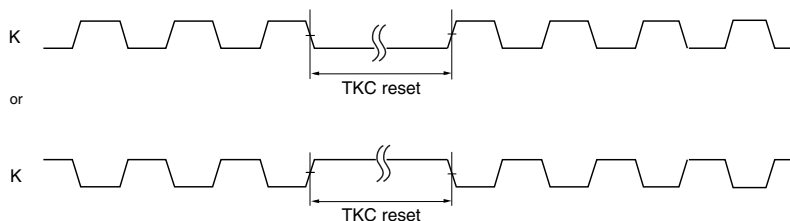
Figure 1. External load at test



# Read and Write Cycle

| Parameter                                                                           | Symbol    | -E33, E33Y<br>(300 MHz) |      | -E35, E35Y<br>(287 MHz) |      | -E40, E40Y<br>(250 MHz) |      | -E50, E50Y<br>(200 MHz) |      | Unit | Note |
|-------------------------------------------------------------------------------------|-----------|-------------------------|------|-------------------------|------|-------------------------|------|-------------------------|------|------|------|
|                                                                                     |           | MIN.                    | MAX. | MIN.                    | MAX. | MIN.                    | MAX. | MIN.                    | MAX. |      |      |
| Clock                                                                               |           |                         |      |                         |      |                         |      |                         |      |      |      |
| Average Clock cycle time<br>(K, K#, C, C#)                                          | TKHKH     | 3.3                     | 8.4  | 3.5                     | 8.4  | 4.0                     | 8.4  | 5.0                     | 8.4  | ns   | 1    |
| Clock phase jitter (K, K#, C, C#)                                                   | TKC var   |                         | 0.2  |                         | 0.2  |                         | 0.2  |                         | 0.2  | ns   | 2    |
| Clock HIGH time (K, K#, C, C#)                                                      | TKHKL     | 1.32                    |      | 1.5                     |      | 1.6                     |      | 2.0                     |      | ns   |      |
| Clock LOW time (K, K#, C, C#)                                                       | TKLKH     | 1.32                    |      | 1.5                     |      | 1.6                     |      | 2.0                     |      | ns   |      |
| Clock HIGH to Clock# HIGH<br>(K → K#, C → C#)                                       | TKHK#H    | 1.49                    |      | 1.7                     |      | 1.8                     |      | 2.2                     |      | ns   |      |
| Clock# HIGH to Clock HIGH<br>(K# → K, C# → C)                                       | TK#HKH    | 1.49                    |      | 1.7                     |      | 1.8                     |      | 2.2                     |      | ns   |      |
| Clock to data clock<br>(K → C, K# → C#)                                             | TKHCH     | 0                       | 1.45 | 0                       | 1.65 | 0                       | 1.8  | 0                       | 2.3  | ns   |      |
| PLL lock time (K, C)                                                                | TKC lock  | 20                      |      | 20                      |      | 20                      |      | 20                      |      | μs   | 3    |
| K static to PLL reset                                                               | TKC reset | 30                      |      | 30                      |      | 30                      |      | 30                      |      | ns   | 4    |
| Output Times                                                                        |           |                         |      |                         |      |                         |      |                         |      |      |      |
| CQ HIGH to CQ# HIGH<br>(CQ → CQ#)                                                   | TCQHCQ#H  | 1.24                    |      | 1.35                    |      | 1.55                    |      | 1.95                    |      | ns   | 5    |
| CQ# HIGH to CQ HIGH<br>(CQ# → CQ)                                                   | TCQ#HCQH  | 1.24                    |      | 1.35                    |      | 1.55                    |      | 1.95                    |      | ns   | 5    |
| C, C# HIGH to output valid                                                          | TCHQV     |                         | 0.45 |                         | 0.45 |                         | 0.45 |                         | 0.45 | ns   |      |
| C, C# HIGH to output hold                                                           | TCHQX     | -0.45                   |      | -0.45                   |      | -0.45                   |      | -0.45                   |      | ns   |      |
| C, C# HIGH to echo clock valid                                                      | TCHCQV    |                         | 0.45 |                         | 0.45 |                         | 0.45 |                         | 0.45 | ns   |      |
| C, C# HIGH to echo clock hold                                                       | TCHCQX    | -0.45                   |      | -0.45                   |      | -0.45                   |      | -0.45                   |      | ns   |      |
| CQ, CQ# HIGH to output valid                                                        | TCQHQV    |                         | 0.27 |                         | 0.3  |                         | 0.3  |                         | 0.35 | ns   | 6    |
| CQ, CQ# HIGH to output hold                                                         | TCQHQX    | -0.27                   |      | -0.3                    |      | -0.3                    |      | -0.35                   |      | ns   | 6    |
| C HIGH to output High-Z                                                             | TCHQZ     |                         | 0.45 |                         | 0.45 |                         | 0.45 |                         | 0.45 | ns   |      |
| C HIGH to output Low-Z                                                              | TCHQX1    | -0.45                   |      | -0.45                   |      | -0.45                   |      | -0.45                   |      | ns   |      |
| Setup Times                                                                         |           |                         |      |                         |      |                         |      |                         |      |      |      |
| Address valid to K rising edge                                                      | TAVKH     | 0.3                     |      | 0.35                    |      | 0.35                    |      | 0.4                     |      | ns   | 7    |
| Control inputs (R#, W#) valid to<br>K rising edge                                   | TIVKH     | 0.3                     |      | 0.35                    |      | 0.35                    |      | 0.4                     |      | ns   | 7    |
| Data inputs and write data<br>select<br>inputs (BWx#) valid to<br>K, K# rising edge | TDVKH     | 0.3                     |      | 0.35                    |      | 0.35                    |      | 0.4                     |      | ns   | 7    |
| Hold Times                                                                          |           |                         |      |                         |      |                         |      |                         |      |      |      |
| K rising edge to address hold                                                       | TKHAX     | 0.3                     |      | 0.35                    |      | 0.35                    |      | 0.4                     |      | ns   | 7    |
| K rising edge to control inputs<br>(R#, W#) hold                                    | TKHIX     | 0.3                     |      | 0.35                    |      | 0.35                    |      | 0.4                     |      | ns   | 7    |
| K, K# rising edge to data<br>inputs and write data select<br>inputs (BWx#) hold     | TKHDX     | 0.3                     |      | 0.35                    |      | 0.35                    |      | 0.4                     |      | ns   | 7    |

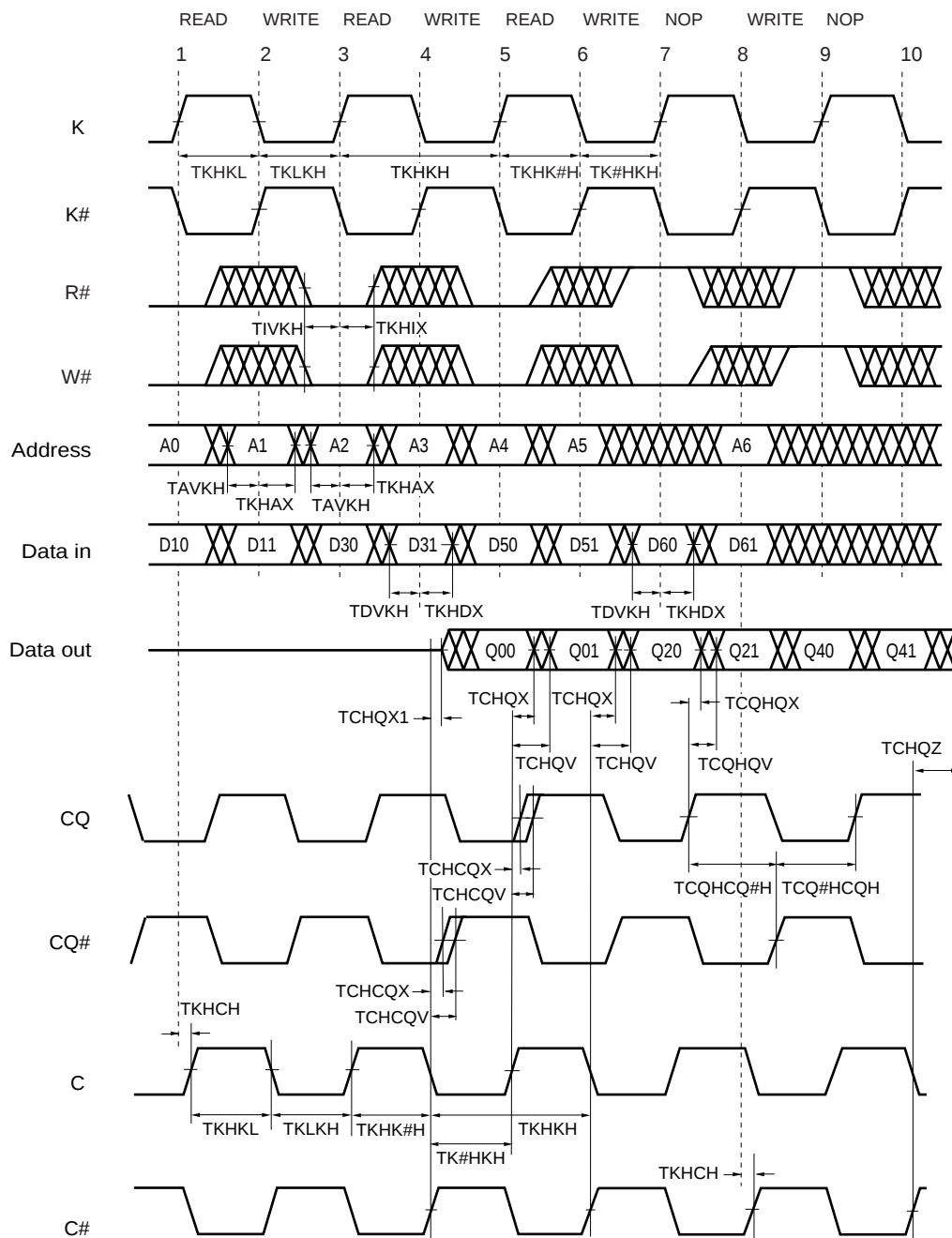
- Notes**
1. When debugging the system or board, these products can operate at a clock frequency slower than TKHKH (MAX.) without the PLL circuit being used, if DLL# = LOW. Read latency (RL) is changed to 1.0 clock cycle in this operation. The AC/DC characteristics cannot be guaranteed, however.
  2. Clock phase jitter is the variance from clock rising edge to the next expected clock rising edge. TKC var (MAX.) indicates a peak-to-peak value.
  3. V<sub>DD</sub> slew rate must be less than 0.1 V DC per 50 ns for PLL lock retention.  
PLL lock time begins once V<sub>DD</sub> and input clock are stable.  
It is recommended that the device is kept NOP (R# = W# = HIGH) during these cycles.
  4. K input is monitored for this operation. See below for the timing.



5. Guaranteed by design.
6. Echo clock is very tightly controlled to data valid / data hold. By design, there is a  $\pm 0.1$  ns variation from echo clock to data. The data sheet parameters reflect tester guardbands and test setup variations.
7. This is a synchronous device. All addresses, data and control lines must meet the specified setup and hold times for all latching clock edges.

- Remarks**
1. This parameter is sampled.
  2. Test conditions as specified with the output loading as shown in AC Test Conditions unless otherwise noted.
  3. Control input signals may not be operated with pulse widths less than TKHKL (MIN.).
  4. If C, C# are tied HIGH, K, K# become the references for C, C# timing parameters.
  5. V<sub>DDQ</sub> is 1.5 V DC.

## Read and Write Timing



**Remarks 1.** Q00 refers to output from address A0+0.

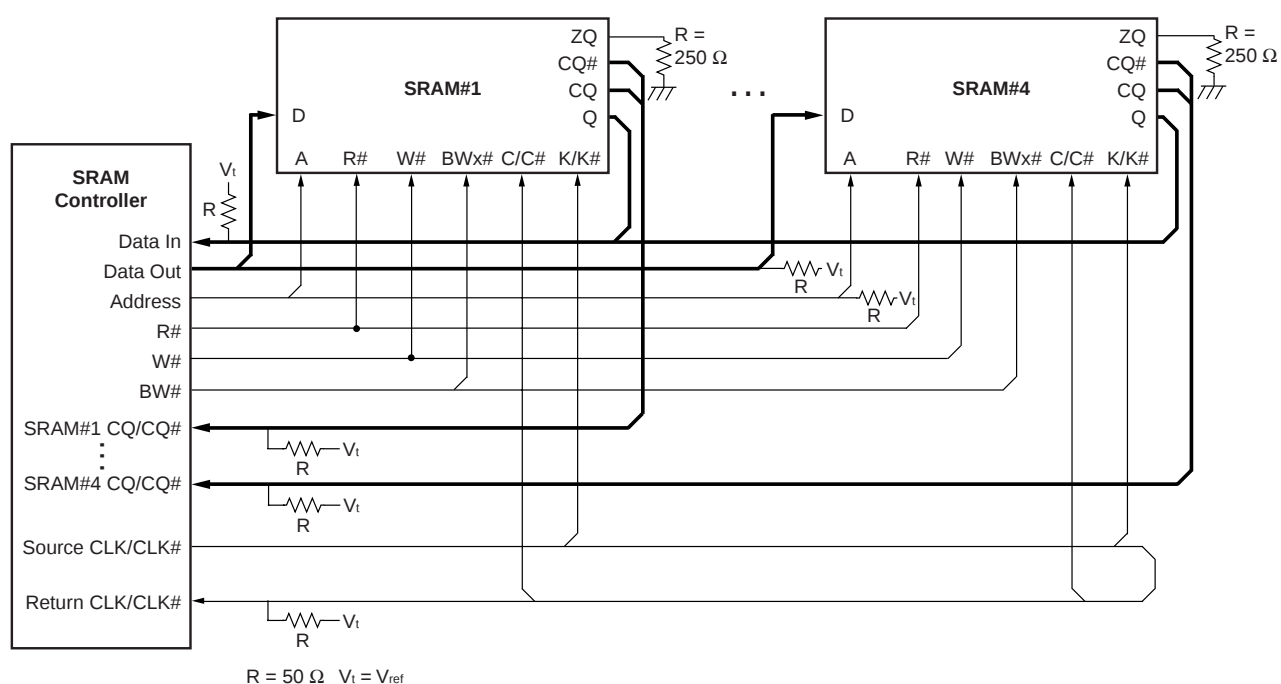
Q01 refers to output from the next internal burst address following A0, i.e., A0+1.

- Outputs are disabled (high impedance) 2.5 clock cycles after the last READ ( $R\# = \text{LOW}$ ) is input in the sequences of [READ/WRITE]-[NOP/WRITE], [READ/WRITE]-[NOP/NOP], [READ/NOP]-[NOP/WRITE] and [READ/NOP]-[NOP/NOP].

- In this example, if address A0 = A1, data Q00 = D10, Q01 = D11.

Write data is forwarded immediately as read results.

## Application Example



**Remark** AC Characteristics are defined at the condition of SRAM outputs, CQ, CQ# and DQ with termination.

## JTAG Specification

These products support a limited set of JTAG functions as in IEEE standard 1149.1.

### Test Access Port (TAP) Pins

| Pin name | Pin assignments | Description                                                                                                                                                                                                                                                             |
|----------|-----------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| TCK      | 2R              | Test Clock Input. All input are captured on the rising edge of TCK and all outputs propagate from the falling edge of TCK.                                                                                                                                              |
| TMS      | 10R             | Test Mode Select. This is the command input for the TAP controller state machine.                                                                                                                                                                                       |
| TDI      | 11R             | Test Data Input. This is the input side of the serial registers placed between TDI and TDO. The register placed between TDI and TDO is determined by the state of the TAP controller state machine and the instruction that is currently loaded in the TAP instruction. |
| TDO      | 1R              | Test Data Output. This is the output side of the serial registers placed between TDI and TDO. Output changes in response to the falling edge of TCK.                                                                                                                    |

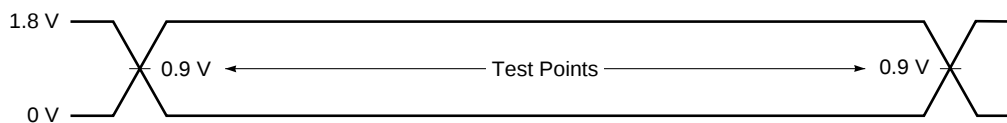
**Remark** The device does not have TRST (TAP reset). The Test-Logic Reset state is entered while TMS is held HIGH for five rising edges of TCK. The TAP controller state is also reset on the SRAM POWER-UP.

### JTAG DC Characteristics (T<sub>A</sub> = 0 to 70°C, V<sub>DD</sub> = 1.8 ± 0.1 V, unless otherwise noted)

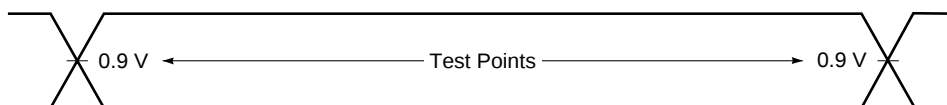
| Parameter                  | Symbol           | Conditions                                                     | MIN. | MAX.                 | Unit |
|----------------------------|------------------|----------------------------------------------------------------|------|----------------------|------|
| JTAG Input leakage current | I <sub>LI</sub>  | 0 V ≤ V <sub>IN</sub> ≤ V <sub>DD</sub>                        | −5.0 | +5.0                 | μA   |
| JTAG I/O leakage current   | I <sub>LO</sub>  | 0 V ≤ V <sub>IN</sub> ≤ V <sub>DD</sub> Q,<br>Outputs disabled | −5.0 | +5.0                 | μA   |
| JTAG input HIGH voltage    | V <sub>IH</sub>  |                                                                | 1.3  | V <sub>DD</sub> +0.3 | V    |
| JTAG input LOW voltage     | V <sub>IL</sub>  |                                                                | −0.3 | +0.5                 | V    |
| JTAG output HIGH voltage   | V <sub>OH1</sub> | I <sub>OH</sub> C  = 100 μA                                    | 1.6  |                      | V    |
|                            | V <sub>OH2</sub> | I <sub>OH</sub> T  = 2 mA                                      | 1.4  |                      | V    |
| JTAG output LOW voltage    | V <sub>OL1</sub> | I <sub>OL</sub> C = 100 μA                                     |      | 0.2                  | V    |
|                            | V <sub>OL2</sub> | I <sub>OL</sub> T = 2 mA                                       |      | 0.4                  | V    |

## JTAG AC Test Conditions

Input waveform (Rise / Fall time  $\leq 1$  ns)

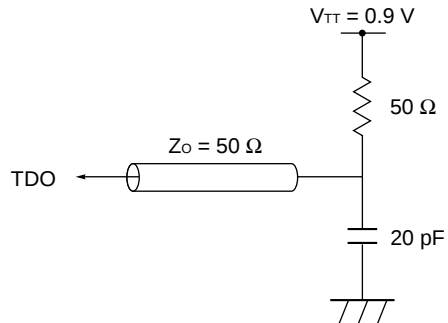


Output waveform



Output load

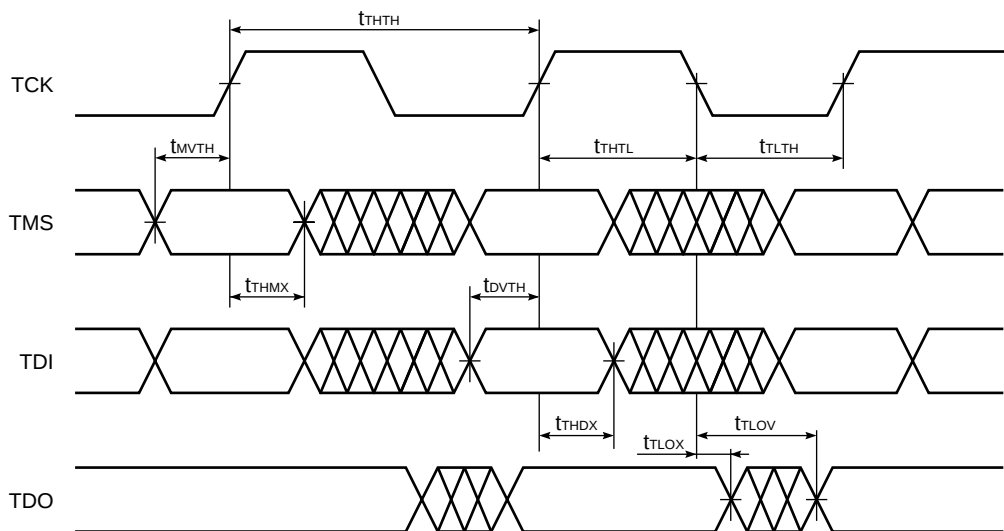
Figure 2. External load at test



JTAG AC Characteristics (T<sub>A</sub> = 0 to 70°C)

| Parameter               | Symbol            | Conditions | MIN. | MAX. | Unit |
|-------------------------|-------------------|------------|------|------|------|
| <b>Clock</b>            |                   |            |      |      |      |
| Clock cycle time        | t <sub>THTH</sub> |            | 50   |      | ns   |
| Clock frequency         | f <sub>TF</sub>   |            |      | 20   | MHz  |
| Clock HIGH time         | t <sub>HTHL</sub> |            | 20   |      | ns   |
| Clock LOW time          | t <sub>TLTH</sub> |            | 20   |      | ns   |
| <b>Output time</b>      |                   |            |      |      |      |
| TCK LOW to TDO unknown  | t <sub>TLOX</sub> |            | 0    |      | ns   |
| TCK LOW to TDO valid    | t <sub>TLOV</sub> |            |      | 10   | ns   |
| <b>Setup time</b>       |                   |            |      |      |      |
| TMS setup time          | t <sub>MVTH</sub> |            | 5    |      | ns   |
| TDI valid to TCK HIGH   | t <sub>DVTH</sub> |            | 5    |      | ns   |
| Capture setup time      | t <sub>CS</sub>   |            | 5    |      | ns   |
| <b>Hold time</b>        |                   |            |      |      |      |
| TMS hold time           | t <sub>THMX</sub> |            | 5    |      | ns   |
| TCK HIGH to TDI invalid | t <sub>THDX</sub> |            | 5    |      | ns   |
| Capture hold time       | t <sub>CH</sub>   |            | 5    |      | ns   |

JTAG Timing Diagram



### Scan Register Definition (1)

| Register name        | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                            |
|----------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| Instruction register | The instruction register holds the instructions that are executed by the TAP controller when it is moved into the run-test/idle or the various data register state. The register can be loaded when it is placed between the TDI and TDO pins. The instruction register is automatically preloaded with the IDCODE instruction at power-up whenever the controller is placed in test-logic-reset state.                                                                                                                                                                                                                |
| Bypass register      | The bypass register is a single bit register that can be placed between TDI and TDO. It allows serial test data to be passed through the RAMs TAP to another device in the scan chain with as little delay as possible.                                                                                                                                                                                                                                                                                                                                                                                                |
| ID register          | The ID Register is a 32 bit register that is loaded with a device and vendor specific 32 bit code when the controller is put in capture-DR state with the IDCODE command loaded in the instruction register. The register is then placed between the TDI and TDO pins when the controller is moved into shift-DR state.                                                                                                                                                                                                                                                                                                |
| Boundary register    | The boundary register, under the control of the TAP controller, is loaded with the contents of the RAMs I/O ring when the controller is in capture-DR state and then is placed between the TDI and TDO pins when the controller is moved to shift-DR state. Several TAP instructions can be used to activate the boundary register.<br>The Scan Exit Order tables describe which device bump connects to each boundary register location. The first column defines the bit's position in the boundary register. The second column is the name of the input or I/O at the bump and the third column is the bump number. |

### Scan Register Definition (2)

| Register name        | Bit size | Unit |
|----------------------|----------|------|
| Instruction register | 3        | bit  |
| Bypass register      | 1        | bit  |
| ID register          | 32       | bit  |
| Boundary register    | 109      | bit  |

### ID Register Definition

| Part number  | Organization | ID [31:28] vendor revision no. | ID [27:12] part no. | ID [11:1] vendor ID no. | ID [0] fix bit |
|--------------|--------------|--------------------------------|---------------------|-------------------------|----------------|
| μPD44325092B | 4M x 9       | XXXX                           | 0000 0000 0100 1010 | 00000010000             | 1              |
| μPD44325182B | 2M x 18      | XXXX                           | 0000 0000 0100 1011 | 00000010000             | 1              |
| μPD44325362B | 1M x 36      | XXXX                           | 0000 0000 0100 1100 | 00000010000             | 1              |

# SCAN Exit Order

| Bit no. | Signal name |     |     | Bump ID |
|---------|-------------|-----|-----|---------|
|         | x9          | x18 | x36 |         |
| 1       | C#          |     |     | 6R      |
| 2       | C           |     |     | 6P      |
| 3       | A           |     |     | 6N      |
| 4       | A           |     |     | 7P      |
| 5       | A           |     |     | 7N      |
| 6       | A           |     |     | 7R      |
| 7       | A           |     |     | 8R      |
| 8       | A           |     |     | 8P      |
| 9       | A           |     |     | 9R      |
| 10      | Q0          |     |     | 11P     |
| 11      | D0          |     |     | 10P     |
| 12      | NC          | NC  | D9  | 10N     |
| 13      | NC          | NC  | Q9  | 9P      |
| 14      | NC          | Q1  | Q1  | 10M     |
| 15      | NC          | D1  | D1  | 11N     |
| 16      | NC          | NC  | D10 | 9M      |
| 17      | NC          | NC  | Q10 | 9N      |
| 18      | Q1          | Q2  | Q2  | 11L     |
| 19      | D1          | D2  | D2  | 11M     |
| 20      | NC          | NC  | D11 | 9L      |
| 21      | NC          | NC  | Q11 | 10L     |
| 22      | NC          | Q3  | Q3  | 11K     |
| 23      | NC          | D3  | D3  | 10K     |
| 24      | NC          | NC  | D12 | 9J      |
| 25      | NC          | NC  | Q12 | 9K      |
| 26      | Q2          | Q4  | Q4  | 10J     |
| 27      | D2          | D4  | D4  | 11J     |
| 28      | ZQ          |     |     | 11H     |
| 29      | NC          | NC  | D13 | 10G     |
| 30      | NC          | NC  | Q13 | 9G      |
| 31      | NC          | Q5  | Q5  | 11F     |
| 32      | NC          | D5  | D5  | 11G     |
| 33      | NC          | NC  | D14 | 9F      |
| 34      | NC          | NC  | Q14 | 10F     |
| 35      | Q3          | Q6  | Q6  | 11E     |
| 36      | D3          | D6  | D6  | 10E     |

| Bit no. | Signal name |      |      | Bump ID |
|---------|-------------|------|------|---------|
|         | x9          | x18  | x36  |         |
| 37      | NC          | NC   | D15  | 10D     |
| 38      | NC          | NC   | Q15  | 9E      |
| 39      | NC          | Q7   | Q7   | 10C     |
| 40      | NC          | D7   | D7   | 11D     |
| 41      | NC          | NC   | D16  | 9C      |
| 42      | NC          | NC   | Q16  | 9D      |
| 43      | Q4          | Q8   | Q8   | 11B     |
| 44      | D4          | D8   | D8   | 11C     |
| 45      | NC          | NC   | D17  | 9B      |
| 46      | NC          | NC   | Q17  | 10B     |
| 47      | CQ          |      |      | 11A     |
| 48      | A           | VSS  | VSS  | 10A     |
| 49      | A           |      |      | 9A      |
| 50      | A           |      |      | 8B      |
| 51      | A           |      |      | 7C      |
| 52      | A           |      |      | 6C      |
| 53      | R#          |      |      | 8A      |
| 54      | NC          | NC   | BW1# | 7A      |
| 55      | BW0#        |      |      | 7B      |
| 56      | K           |      |      | 6B      |
| 57      | K#          |      |      | 6A      |
| 58      | NC          | NC   | BW3# | 5B      |
| 59      | NC          | BW1# | BW2# | 5A      |
| 60      | W#          |      |      | 4A      |
| 61      | A           |      |      | 5C      |
| 62      | A           |      |      | 4B      |
| 63      | A           | A    | NC   | 3A      |
| 64      | VSS         |      |      | 2A      |
| 65      | CQ#         |      |      | 1A      |
| 66      | NC          | Q9   | Q18  | 2B      |
| 67      | NC          | D9   | D18  | 3B      |
| 68      | NC          | NC   | D27  | 1C      |
| 69      | NC          | NC   | Q27  | 1B      |
| 70      | NC          | Q10  | Q19  | 3D      |
| 71      | NC          | D10  | D19  | 3C      |
| 72      | NC          | NC   | D28  | 1D      |

| Bit no. | Signal name |     |     | Bump ID  |
|---------|-------------|-----|-----|----------|
|         | x9          | x18 | x36 |          |
| 73      | NC          | NC  | Q28 | 2C       |
| 74      | Q5          | Q11 | Q20 | 3E       |
| 75      | D5          | D11 | D20 | 2D       |
| 76      | NC          | NC  | D29 | 2E       |
| 77      | NC          | NC  | Q29 | 1E       |
| 78      | NC          | Q12 | Q21 | 2F       |
| 79      | NC          | D12 | D21 | 3F       |
| 80      | NC          | NC  | D30 | 1G       |
| 81      | NC          | NC  | Q30 | 1F       |
| 82      | Q6          | Q13 | Q22 | 3G       |
| 83      | D6          | D13 | D22 | 2G       |
| 84      | DLL#        |     |     | 1H       |
| 85      | NC          | NC  | D31 | 1J       |
| 86      | NC          | NC  | Q31 | 2J       |
| 87      | NC          | Q14 | Q23 | 3K       |
| 88      | NC          | D14 | D23 | 3J       |
| 89      | NC          | NC  | D32 | 2K       |
| 90      | NC          | NC  | Q32 | 1K       |
| 91      | Q7          | Q15 | Q24 | 2L       |
| 92      | D7          | D15 | D24 | 3L       |
| 93      | NC          | NC  | D33 | 1M       |
| 94      | NC          | NC  | Q33 | 1L       |
| 95      | NC          | Q16 | Q25 | 3N       |
| 96      | NC          | D16 | D25 | 3M       |
| 97      | NC          | NC  | D34 | 1N       |
| 98      | NC          | NC  | Q34 | 2M       |
| 99      | Q8          | Q17 | Q26 | 3P       |
| 100     | D8          | D17 | D26 | 2N       |
| 101     | NC          | NC  | D35 | 2P       |
| 102     | NC          | NC  | Q35 | 1P       |
| 103     | A           |     |     | 3R       |
| 104     | A           |     |     | 4R       |
| 105     | A           |     |     | 4P       |
| 106     | A           |     |     | 5P       |
| 107     | A           |     |     | 5N       |
| 108     | A           |     |     | 5R       |
| 109     | —           |     |     | Internal |

**Remarks** Bump ID 10A of bit no. 48 can also be used as NC if the product is x18 or x36.

Bump ID 2A of bit no. 64 can also be used as NC.

The register always indicates LOW, however.

## JTAG Instructions

| Instructions     | Description                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |
|------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| EXTEST           | The EXTEST instruction allows circuitry external to the component package to be tested. Boundary-scan register cells at output pins are used to apply test vectors, while those at input pins capture test results. Typically, the first test vector to be applied using the EXTEST instruction will be shifted into the boundary scan register using the PRELOAD instruction. Thus, during the update-IR state of EXTEST, the output drive is turned on and the PRELOAD data is driven onto the output pins.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                      |
| IDCODE           | The IDCODE instruction causes the ID ROM to be loaded into the ID register when the controller is in capture-DR mode and places the ID register between the TDI and TDO pins in shift-DR mode. The IDCODE instruction is the default instruction loaded in at power up and any time the controller is placed in the test-logic-reset state.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                        |
| BYPASS           | When the BYPASS instruction is loaded in the instruction register, the bypass register is placed between TDI and TDO. This occurs when the TAP controller is moved to the shift-DR state. This allows the board level scan path to be shortened to facilitate testing of other devices in the scan path.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                           |
| SAMPLE / PRELOAD | SAMPLE / PRELOAD is a Standard 1149.1 mandatory public instruction. When the SAMPLE / PRELOAD instruction is loaded in the instruction register, moving the TAP controller into the capture-DR state loads the data in the RAMs input and DQ pins into the boundary scan register. Because the RAM clock(s) are independent from the TAP clock (TCK) it is possible for the TAP to attempt to capture the I/O ring contents while the input buffers are in transition (i.e., in a metastable state). Although allowing the TAP to sample metastable input will not harm the device, repeatable results cannot be expected. RAM input signals must be stabilized for long enough to meet the TAPs input data capture setup plus hold time (tCS plus tCH). The RAMs clock inputs need not be paused for any other TAP operation except capturing the I/O ring contents into the boundary scan register. Moving the controller to shift-DR state then places the boundary scan register between the TDI and TDO pins. |
| SAMPLE-Z         | If the SAMPLE-Z instruction is loaded in the instruction register, all RAM DQ pins are forced to an inactive drive state (high impedance) and the boundary register is connected between TDI and TDO when the TAP controller is moved to the shift-DR state.                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                                       |

## JTAG Instruction Coding

| IR2 | IR1 | IR0 | Instruction      | Note |
|-----|-----|-----|------------------|------|
| 0   | 0   | 0   | EXTEST           |      |
| 0   | 0   | 1   | IDCODE           |      |
| 0   | 1   | 0   | SAMPLE-Z         | 1    |
| 0   | 1   | 1   | RESERVED         | 2    |
| 1   | 0   | 0   | SAMPLE / PRELOAD |      |
| 1   | 0   | 1   | RESERVED         | 2    |
| 1   | 1   | 0   | RESERVED         | 2    |
| 1   | 1   | 1   | BYPASS           |      |

- Notes**
1. TRISTATE all DQ pins and CAPTURE the pad values into a SERIAL SCAN LATCH.
  2. Do not use this instruction code because the vendor uses it to evaluate this product.

## Output Pin States of CQ, CQ# and Q

| Instructions | Control-Register Status | Output Pin Status |        |
|--------------|-------------------------|-------------------|--------|
|              |                         | CQ, CQ#           | Q      |
| EXTEST       | 0                       | Update            | High-Z |
|              | 1                       | Update            | Update |
| IDCODE       | 0                       | SRAM              | SRAM   |
|              | 1                       | SRAM              | SRAM   |
| SAMPLE-Z     | 0                       | High-Z            | High-Z |
|              | 1                       | High-Z            | High-Z |
| SAMPLE       | 0                       | SRAM              | SRAM   |
|              | 1                       | SRAM              | SRAM   |
| BYPASS       | 0                       | SRAM              | SRAM   |
|              | 1                       | SRAM              | SRAM   |

**Remark** The output pin statuses during each instruction vary according to the Control-Register status (value of Boundary Scan Register, bit no. 109).

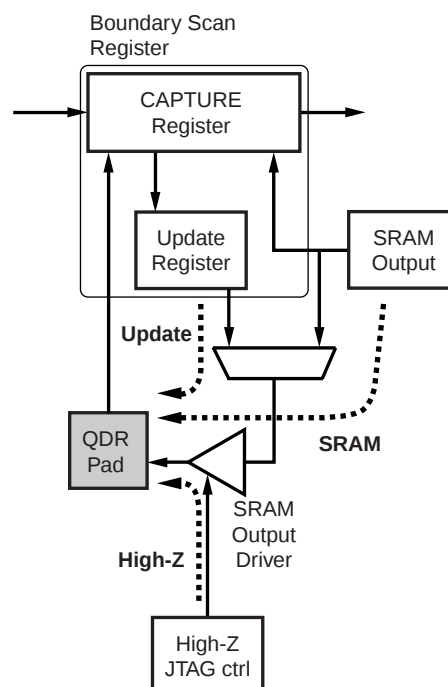
There are three statuses:

**Update** : Contents of the “Update Register” are output to the output pin (QDR Pad).

**SRAM** : Contents of the SRAM internal output “SRAM Output” are output to the output pin (QDR Pad).

**High-Z** : The output pin (QDR Pad) becomes high impedance by controlling of the “High-Z JTAG ctrl”.

The Control-Register status is set during Update-DR at the EXTEST or SAMPLE instruction.



# Boundary Scan Register Status of Output Pins CQ, CQ# and Q

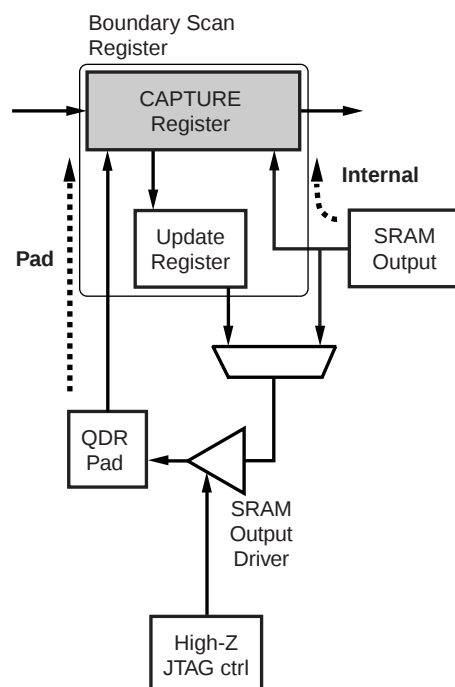
| Instructions | SRAM Status  | Boundary Scan Register Status |          | Note          |
|--------------|--------------|-------------------------------|----------|---------------|
|              |              | CQ,CQ#                        | Q        |               |
| EXTEST       | READ (Low-Z) | Pad                           | Pad      |               |
|              | NOP (High-Z) | Pad                           | Pad      |               |
| IDCODE       | READ (Low-Z) | –                             | –        | No definition |
|              | NOP (High-Z) | –                             | –        |               |
| SAMPLE-Z     | READ (Low-Z) | Pad                           | Pad      |               |
|              | NOP (High-Z) | Pad                           | Pad      |               |
| SAMPLE       | READ (Low-Z) | Internal                      | Internal |               |
|              | NOP (High-Z) | Internal                      | Pad      |               |
| BYPASS       | READ (Low-Z) | –                             | –        | No definition |
|              | NOP (High-Z) | –                             | –        |               |

**Remark** The Boundary Scan Register statuses during execution each instruction vary according to the instruction code and SRAM operation mode.

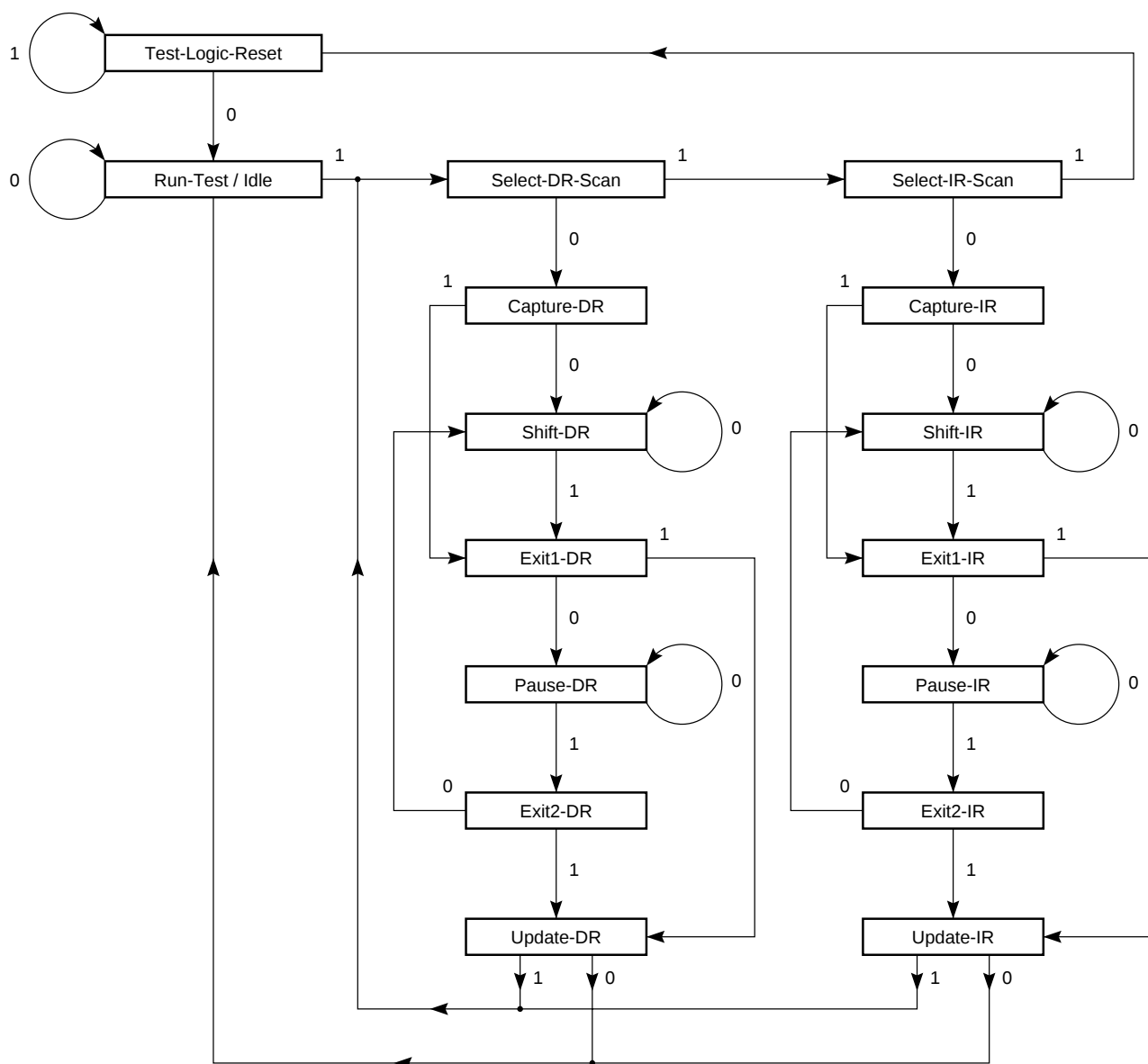
There are two statuses:

**Pad** : Contents of the output pin (QDR Pad) are captured in the “CAPTURE Register” in the Boundary Scan Register.

**Internal** : Contents of the SRAM internal output “SRAM Output” are captured in the “CAPTURE Register” in the Boundary Scan Register.



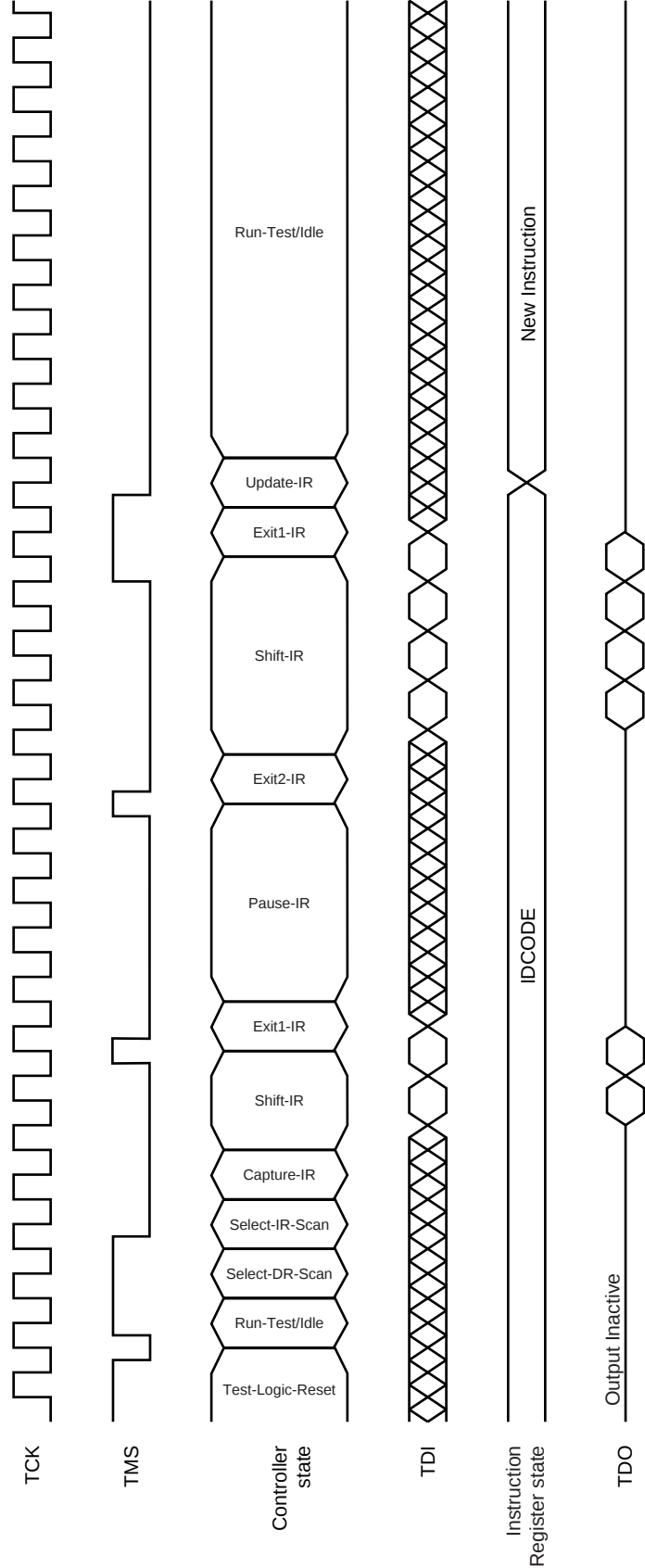
## TAP Controller State Diagram



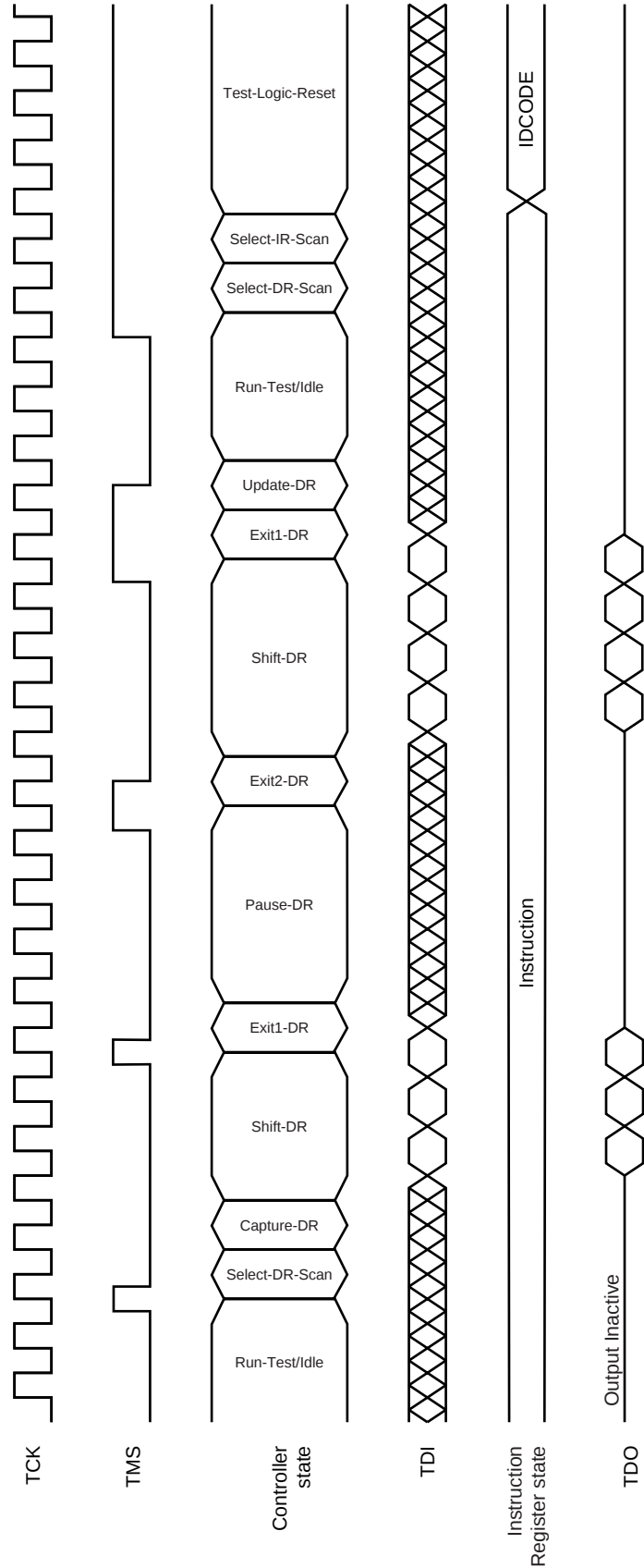
## Disabling the Test Access Port

It is possible to use this device without utilizing the TAP. To disable the TAP Controller without interfering with normal operation of the device, TCK must be tied to  $V_{SS}$  to preclude mid level inputs. TDI and TMS may be left open but fix them to  $V_{DD}$  via a resistor of about 1 kΩ when the TAP controller is not used. TDO should be left unconnected also when the TAP controller is not used.

Test Logic Operation (Instruction Scan)

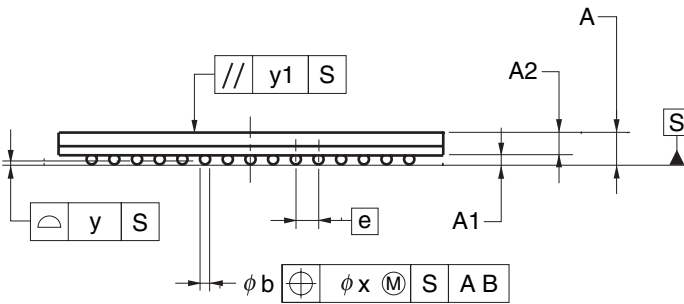
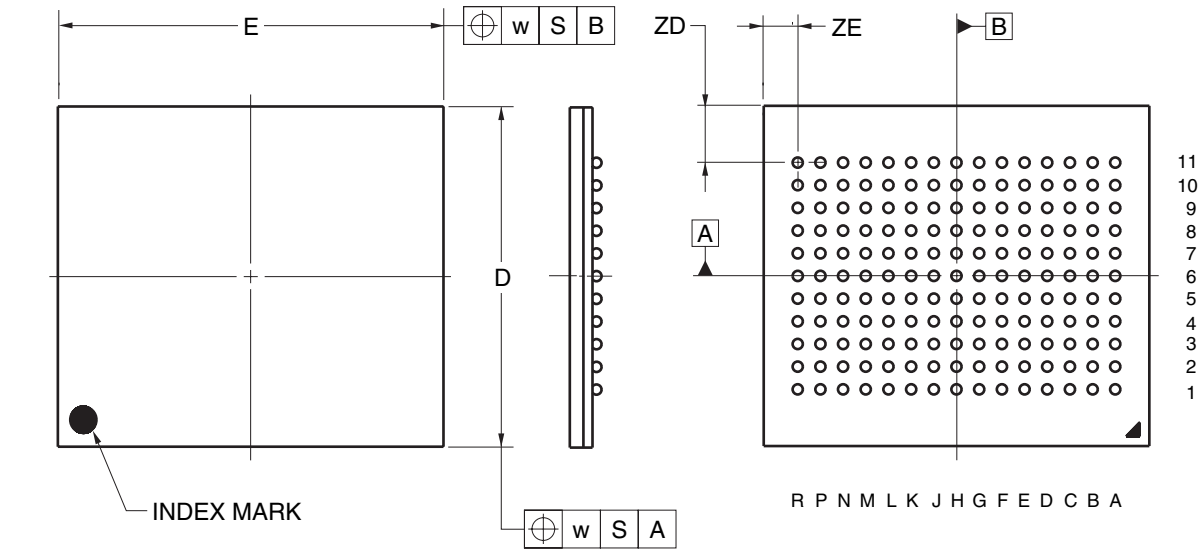


Test Logic (Data Scan)



Package Dimensions

165-PIN PLASTIC BGA(15x17)



(UNIT:mm)

| ITEM | DIMENSIONS                             |
|------|----------------------------------------|
| D    | 15.00±0.10                             |
| E    | 17.00±0.10                             |
| w    | 0.30                                   |
| A    | 1.35±0.11                              |
| A1   | 0.37±0.05                              |
| A2   | 0.98                                   |
| e    | 1.00                                   |
| b    | 0.50 <sup>+0.10</sup> <sub>-0.05</sub> |
| x    | 0.10                                   |
| y    | 0.15                                   |
| y1   | 0.25                                   |
| ZD   | 2.50                                   |
| ZE   | 1.50                                   |

P165F5-100-FQ1-1

© Renesas Electronics Corporation 2010

## **Recommended Soldering Condition**

Please consult with our sales offices for soldering conditions of these products.

## **Types of Surface Mount Devices**

μPD44325092BF5-FQ1 : 165-pin PLASTIC BGA (15 x 17)

μPD44325182BF5-FQ1 : 165-pin PLASTIC BGA (15 x 17)

μPD44325362BF5-FQ1 : 165-pin PLASTIC BGA (15 x 17)

## **Quality Grade**

- A quality grade of the products is “Standard”.
- Anti-radioactive design is not implemented in the products.
- Semiconductor devices have the possibility of unexpected defects by affection of cosmic ray that reach to the ground and so forth.

|                         |                                                                                               |
|-------------------------|-----------------------------------------------------------------------------------------------|
| <b>Revision History</b> | <b><math>\mu</math>PD44325092B, <math>\mu</math>PD44325182B , <math>\mu</math>PD44325362B</b> |
|-------------------------|-----------------------------------------------------------------------------------------------|

| Rev.        | Date      | Description |                                                                    |
|-------------|-----------|-------------|--------------------------------------------------------------------|
|             |           | Page        | Summary                                                            |
| 1st edition | '08.03.01 | -           | New Preliminary Data Sheet                                         |
| 2nd edition | '10.03.01 | P14         | DC Characteristics (Modification, Spec of $I_{DD}$ and $I_{SB1}$ ) |
|             |           | P15         | Thermal Characteristics (Modification, Spec)                       |
| Rev.1.00    | '10.09.10 | Throughout  | Preliminary Data Sheet → Data Sheet                                |
| Rev.2.00    | '11.08.11 | Throughout  | Add Lead and the extended temperature operation product            |